

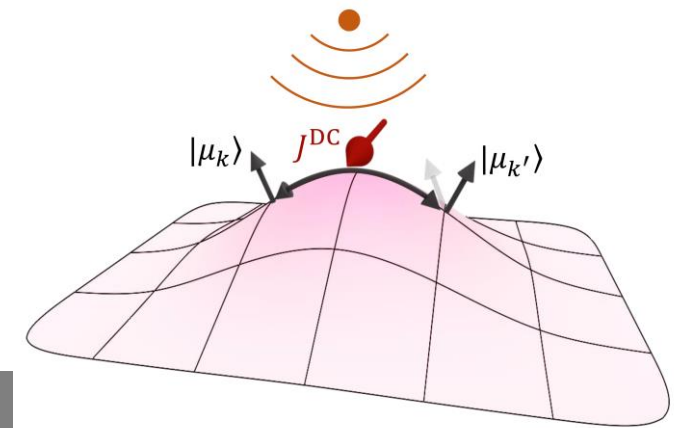
Nonlinear Hall effect induced by a quantum metric dipole in antiferromagnetic heterostructures

Thaís Victa Trevisan (trevisan@berkeley.edu)

Lawrence Berkeley National Laboratory and UC Berkeley

Gao, Liu, Qiu, Gosh, Trevisan et al., Science (2023) - DOI: 10.1126/science.adf1506

ICTP, São Paulo, Brazil – June 19th 2023



Professor Eduardo Miranda taught me:



Classical
Mechanics II

Quantum Theory of
Many-Body Systems

Electrodynamics I



UNIVERSITY OF CAMPINAS

Quantum Theory of Many-Body Systems

Portanto:

$$\langle \Phi_0 | T [\hat{U}(t_2, -\infty) \hat{\psi}_\sigma(\vec{x}_1, t_1) \hat{\psi}_\sigma^\dagger(\vec{x}_2, t_2)] | \Phi_0 \rangle =$$

$$\langle \Phi_0 | \hat{U}(t_2, -\infty) | \Phi_0 \rangle = 1 + \text{diagrams} + \dots$$

Desse modo:

$$i G_{\sigma\sigma}(\vec{x}_1, t_1; \vec{x}_2, t_2) = \frac{\left[\text{diagrams} \right]}{\left[\text{diagrams} \right]}$$

→ O denominador $\langle \Phi_0 | \hat{U}(t_2, -\infty) | \Phi_0 \rangle$ cancela sistematicamente os diagramas desconectados do numerador, de modo que para calcular $G_{\sigma\sigma}(\vec{x}_1, t_1; \vec{x}_2, t_2)$ precisamos apenas dos diagramas conectados

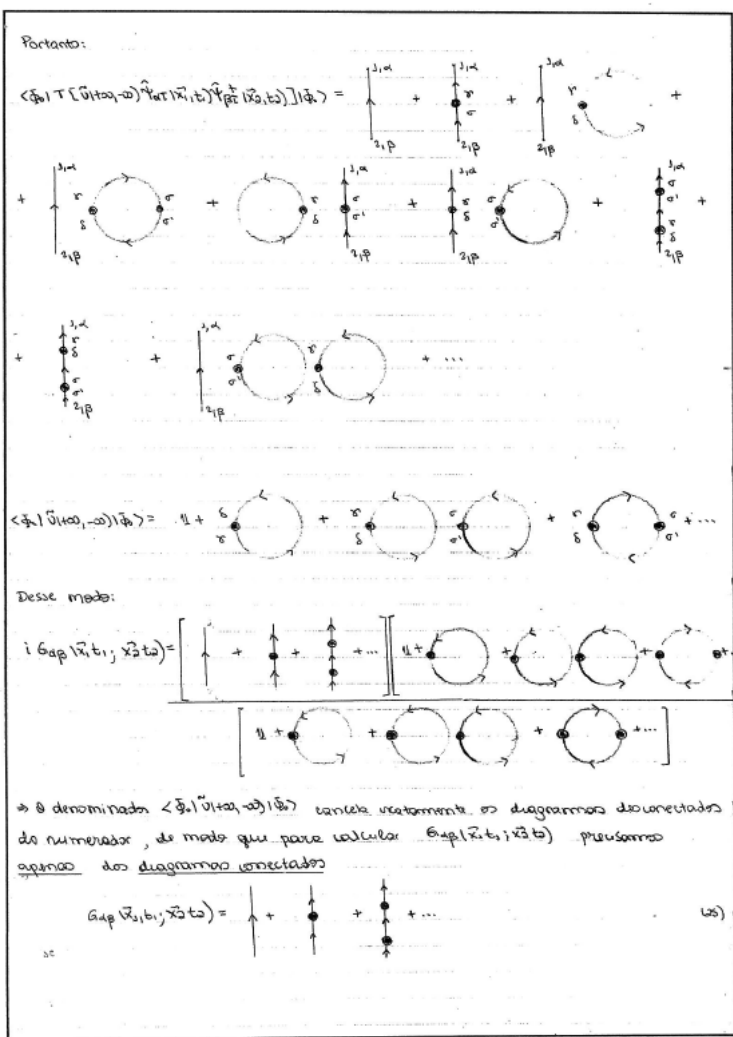
$$G_{\sigma\sigma}(\vec{x}_1, t_1; \vec{x}_2, t_2) = \text{diagrams} \quad (20)$$

Quantum Theory of Many-Body Systems

Unconventional Multiband Superconductivity in Bulk SrTiO_3 and $\text{LaAlO}_3/\text{SrTiO}_3$ Interfaces

Thaís V. Trevisan,^{1,2} Michael Schütt,¹ and Rafael M. Fernandes¹

$$\hat{\Sigma}(\mathbf{k}, \omega_n) = \text{triangle with one dot} + \text{triangle with two dots} + \text{triangle with three dots} + \dots$$



Quantum Theory of Many-Body Systems

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$$\hat{\Sigma}(\mathbf{k}, \omega_n) = \text{[Diagram 1]} + \text{[Diagram 2]} + \text{[Diagram 3]} + \dots$$

The diagrams represent a series of self-energy corrections. Each diagram shows a dashed triangle with a solid line and arrows. The first diagram has one internal vertex. The second has two internal vertices. The third has three internal vertices. The series continues with more terms.

Visualizing band selective enhancement of quasiparticle lifetime in a metallic ferromagnet

Na Hyun Jo^{1,2,5}, Yun Wu^{1,2,5}, Thaís V. Trevisan^{1,2}, Lin-Lin Wang¹, Kyungchan Lee^{1,2,3,4}, Brinda Kuthanazhi^{1,2}, Benjamin Schunk^{1,2}, S. L. Bud'ko^{1,2}, P. C. Canfield^{1,2}, P. P. Orth^{1,2} & Adam Kaminski^{1,2}

$$\mathcal{G}_{\uparrow,\uparrow}^{(2)}(\mathbf{k}, \omega_n) = \text{[Diagram 1]} = \text{[Diagram 2]} + \text{[Diagram 3]}$$

$$\mathcal{G}_{\downarrow,\downarrow}^{(2)}(\mathbf{k}, \omega_n) = \text{[Diagram 1]} = \text{[Diagram 2]} + \text{[Diagram 3]}$$

The diagrams show the second-order Green's function $\mathcal{G}^{(2)}$ for spin-up and spin-down states. Each diagram consists of a solid line with arrows, a dashed line, and a wavy line. The first diagram is a simple solid line. The second diagram has a dashed line loop. The third diagram has a wavy line loop. The diagrams are labeled with spin-up and spin-down arrows.

Portanto:

$$\langle \hat{\phi}_1 | T [\hat{U}(t_0, \omega) \hat{\phi}_2(\mathbf{x}_1, t) \hat{\phi}_2^\dagger(\mathbf{x}_2, t_0)] | \hat{\phi}_1 \rangle = \text{[Diagram 1]} + \text{[Diagram 2]} + \text{[Diagram 3]} + \dots$$

Desse modo:

$$i G_{\text{ap}}(\mathbf{x}_1, t_1; \mathbf{x}_2, t_2) = \text{[Diagram 1]} + \text{[Diagram 2]} + \text{[Diagram 3]} + \dots$$

→ O denominador $\langle \hat{\phi}_1 | \hat{U}(t_0, \omega) | \hat{\phi}_1 \rangle$ cancela sistematicamente os diagramas desconectados do numerador, de modo que para calcular $G_{\text{ap}}(\mathbf{x}_1, t_1; \mathbf{x}_2, t_2)$ precisamos apenas dos diagramas conectados

$$G_{\text{ap}}(\mathbf{x}_1, t_1; \mathbf{x}_2, t_2) = \text{[Diagram 1]} + \text{[Diagram 2]} + \text{[Diagram 3]} + \dots$$

Quantum Theory of Many-Body Systems

Unconventional Multiband Superconductivity in Bulk SrTiO_3 and $\text{LaAlO}_3/\text{SrTiO}_3$ Interfaces

Thaís V. Trevisan,^{1,2} Michael Schütt,¹ and Rafael M. Fernandes¹

$$\hat{\Sigma}(\mathbf{k}, \omega_n) = \text{[diagram: sum of diagrams with vertices and dashed lines]} + \dots$$

Portanto:

$$\langle \hat{\phi}_1^\dagger(\vec{r}_1, t_1) \hat{\phi}_2(\vec{r}_2, t_2) \hat{\phi}_3^\dagger(\vec{r}_3, t_3) \hat{\phi}_4(\vec{r}_4, t_4) \rangle = \text{[diagram: sum of diagrams with vertices and dashed lines]}$$

Thank you, Eduardo!

Happy Birthday

→ O denominador $\langle \hat{\phi}_1^\dagger(\vec{r}_1, t_1) \hat{\phi}_2(\vec{r}_2, t_2) \rangle$ cancela exatamente os diagramas desconectados do numerador, de modo que para calcular $G_{\text{ap}}(\vec{r}_1, t_1; \vec{r}_2, t_2)$ precisamos apenas dos diagramas conectados

$$G_{\text{ap}}(\vec{r}_1, t_1; \vec{r}_2, t_2) = \text{[diagram: sum of diagrams with vertices and dashed lines]} + \dots$$

Probing Majorana wavefunctions in Kitaev honeycomb spin liquids with second-order two-dimensional spectroscopy

Yihua Qiang,^{1,2} Victor L. Quito,^{1,2} Thaís V. Trevisan,^{1,2} and Peter P. Orth^{1,2,3}

¹Department of Physics and Astronomy, Iowa State University, Ames, Iowa 50011, USA

²Ames National Laboratory, Ames, Iowa 50011, USA

³Department of Physics, Saarland University, 66123 Saarbrücken, Germany

(Dated: January 26, 2023)

$$\begin{array}{c} a \\ t_2 \\ b \\ t_1 \\ c \end{array} \begin{array}{|c|} \hline |0\rangle \langle 0| \\ \hline |j\rangle \langle 0| \\ \hline |i\rangle \langle 0| \\ \hline |0\rangle \langle 0| \\ \hline \end{array}$$

(Victor Quito talk on Wednesday)

*Workshop on Strong Electron Correlations in Quantum Materials:
Inhomogeneities Frustration, and Topology*

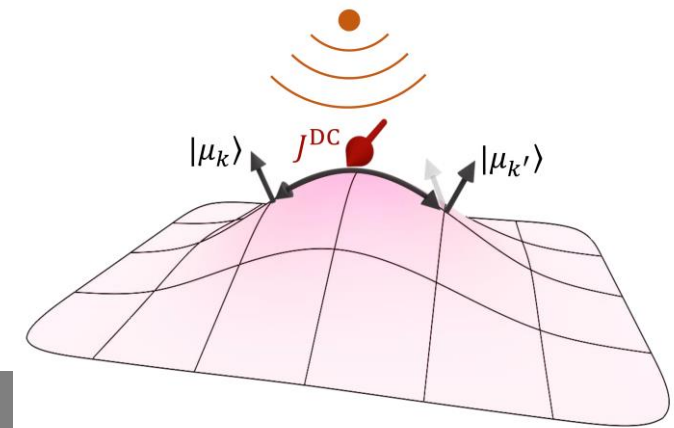
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Multi-institute collaboration through the Center for the Advancement of Topological Semimetals

Theory collaborators:

- Peter P. Orth (Iowa State University)
- Liang Fu (MIT)
- Arun Bansil (Northeastern University)
- David C. Bell (Harvard)
- Bahadur Singh (Tata Institute of Fundamental Research)
- Tay-Rong Chang (National Cheng Kung University)

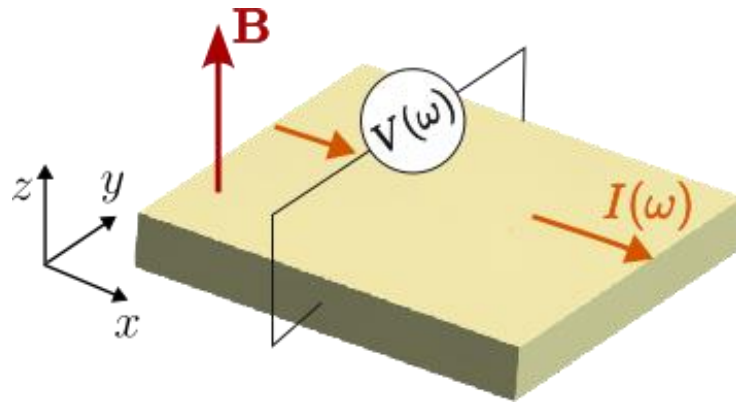
Experiment collaborators:

- Su-Yang Xu (Harvard)
- Qiong Ma (Boston College)
- Chunhui Rita Du (UC San Diego)
- Ni Ni (UCLA)
- Takashi Taniguchi (National Institute for Materials Science)

- **Introduction**
 - Generalities of the Hall effects
 - **Quantum metric:** what it is and where it appears
 - Theory of the **intrinsic quantum metric anomalous Hall effect**
- **The quantum metric Hall effect in MnBi_2Te_4 and BP heterostructure**
 - An ideal platform for the quantum metric Hall effect
 - Minimal model
- **Summary**

The Hall effect

Linear Hall effect:

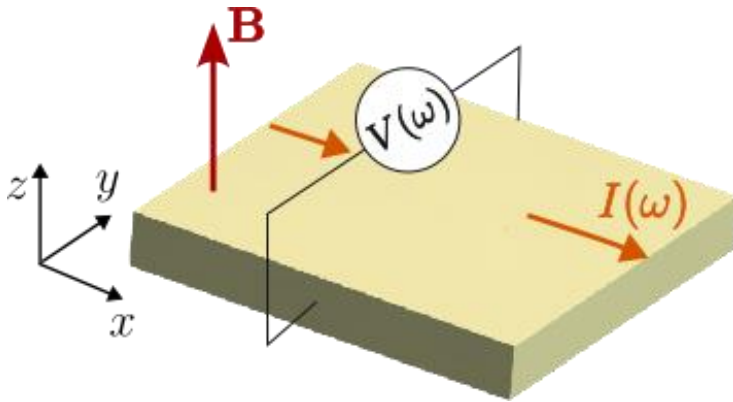


- External $\mathbf{B} \Rightarrow$ normal Hall
[E. Hall, Am. J. Math. (1879)]

The Hall effect

Linear Hall effect:

- External $\mathbf{B} \Rightarrow$ normal Hall
[E. Hall, Am. J. Math. (1879)]



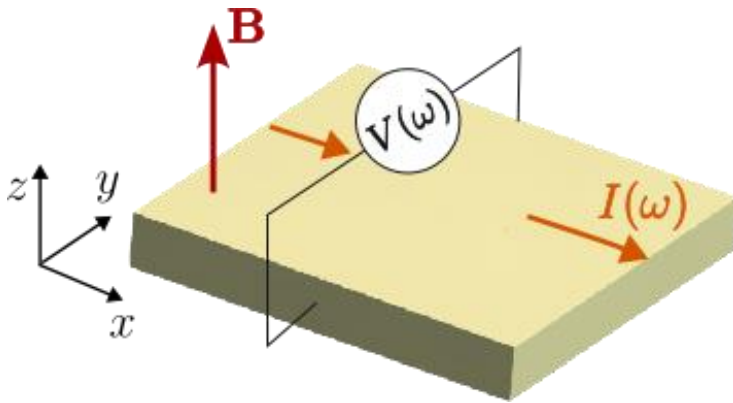
$$J_x(\omega) = \sigma_{xy}(\omega) E_y(\omega)$$

Hall conductivity

[N. Nagaosa et al., Rev. Mod. Phys. 82 (2010)]

The Hall effect

Linear Hall effect:



$$J_x(\omega) = \sigma_{xy}(\omega) E_y(\omega)$$

Hall conductivity

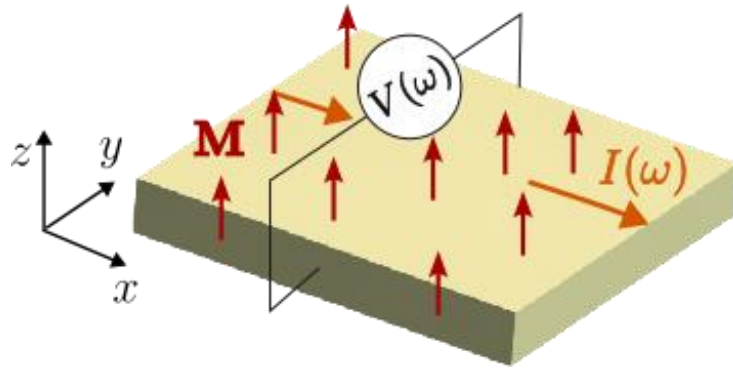
- External $\mathbf{B} \Rightarrow$ normal Hall
[E. Hall, Am. J. Math. (1879)]

$$\rho_{xy} = \frac{1}{\sigma_{xy}} = \frac{1}{ne} B$$

carrier density

The Hall effect

Linear Hall effect:



$$J_x(\omega) = \sigma_{xy}(\omega) E_y(\omega)$$

Hall conductivity

- External $\mathbf{B} \Rightarrow$ normal Hall
[E. Hall, Am. J. Math. (1879)]

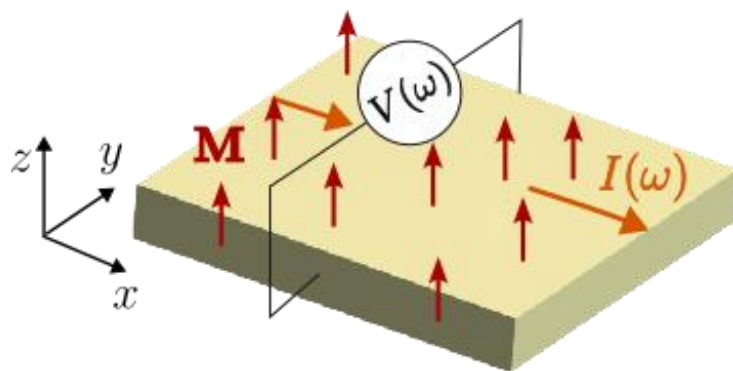
$$\rho_{xy} = \frac{1}{\sigma_{xy}} = \frac{1}{ne} B$$

carrier density

- Intrinsic $\mathbf{M} \Rightarrow$ anomalous Hall
[E. Hall, Philos. Mag. (1881)]

The Hall effect

Linear Hall effect:



$$J_x(\omega) = \sigma_{xy}(\omega) E_y(\omega)$$

Hall conductivity

- External $\mathbf{B} \Rightarrow$ normal Hall
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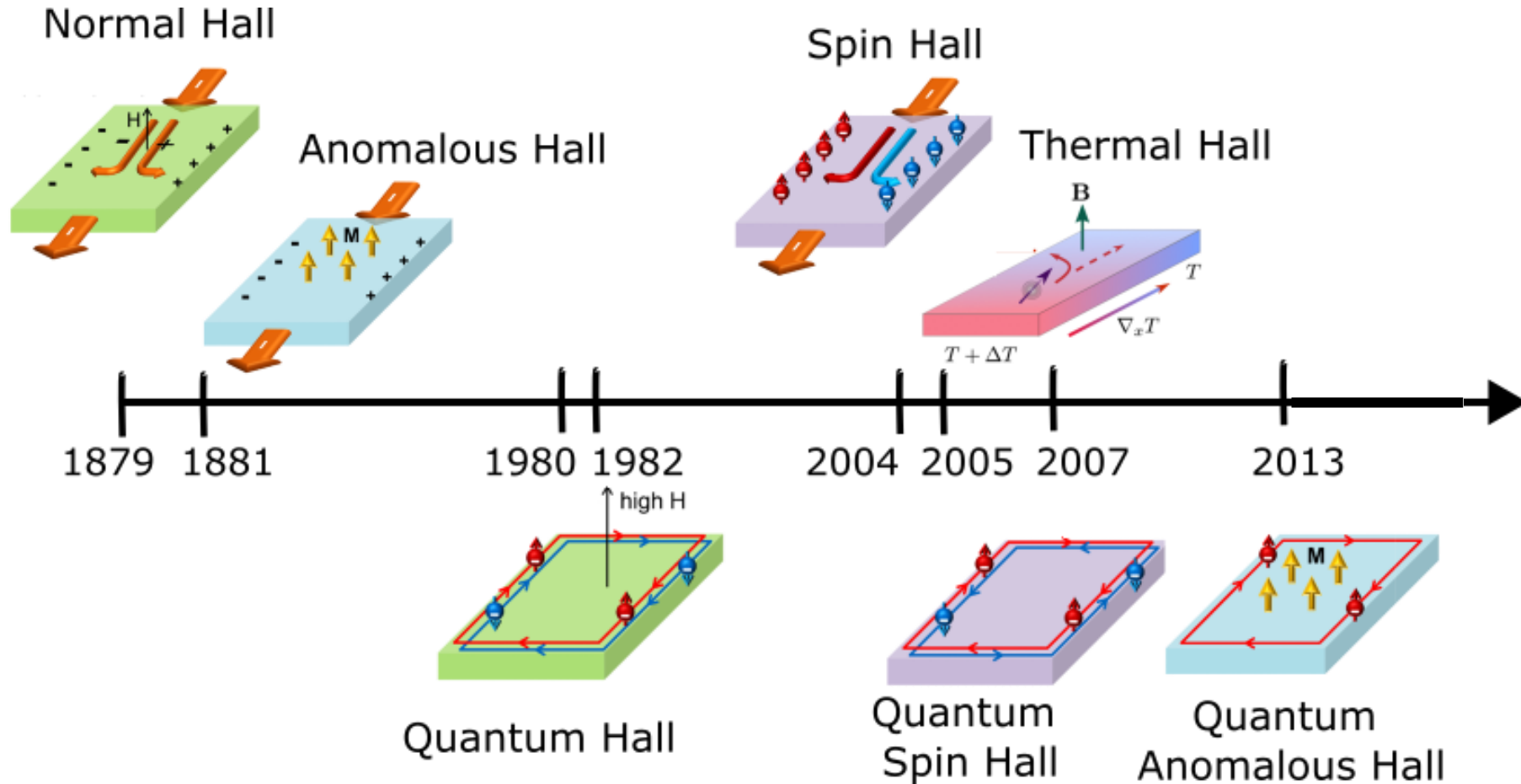
$$\rho_{xy} = \frac{1}{\sigma_{xy}} = \frac{1}{ne} B$$

carrier density

- Intrinsic $\mathbf{M} \Rightarrow$ anomalous Hall
[E. Hall, Philos. Mag. (1881)]

- ➡ Require break of time-reversal symmetry
- ➡ Different microscopic mechanism

The Hall effect family grows

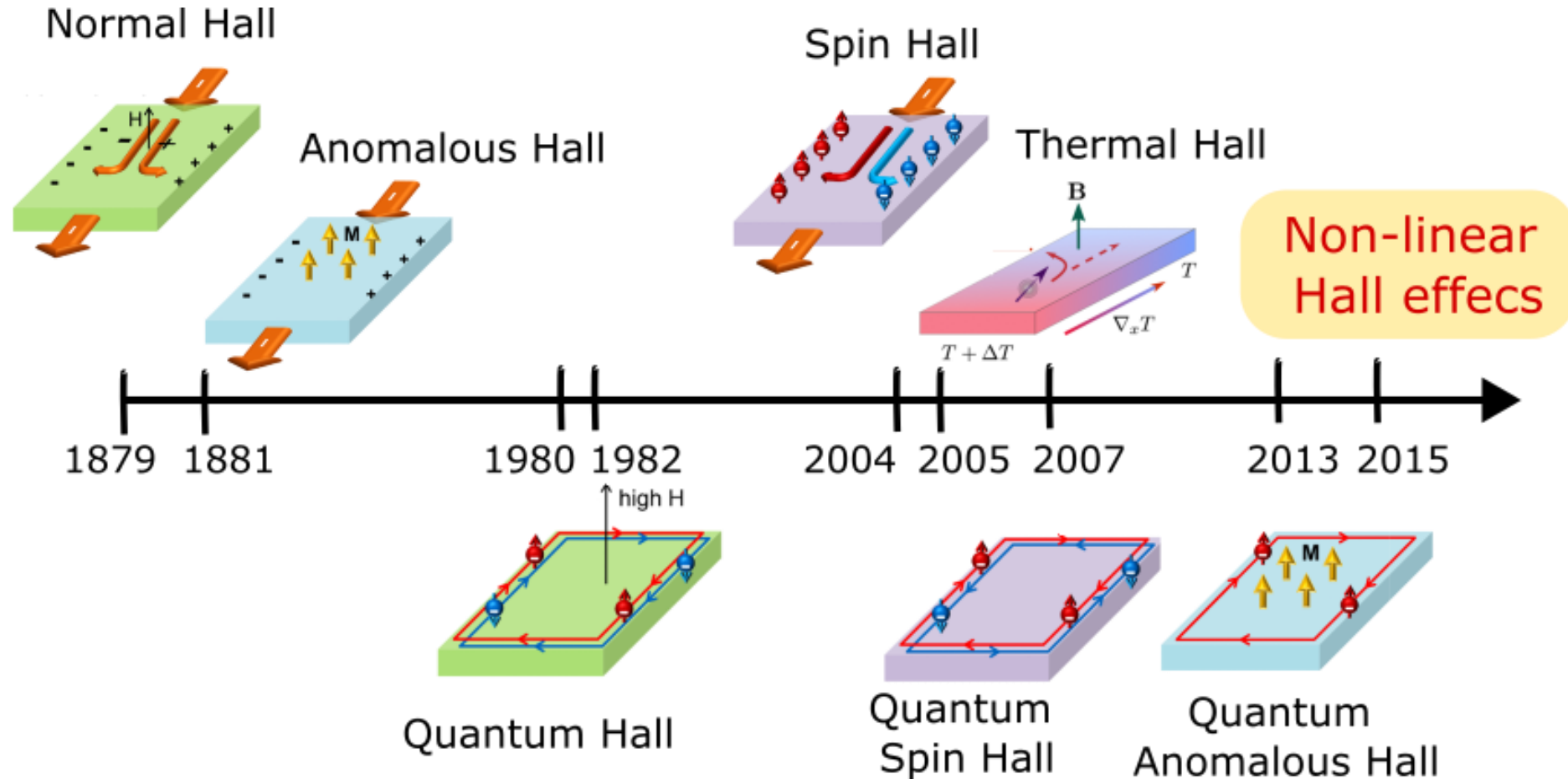


1980: Integer Quantum Hall

1982: Fractional Quantum Hall

[Adapted from C. Chang et al. J. Phys. Cond. Matt. (2016), R. Samajdar et al. PRB (2019) and Z.Z. Du et al. Nat. Phys. (2021)]

The Hall effect family grows



1980: Integer Quantum Hall

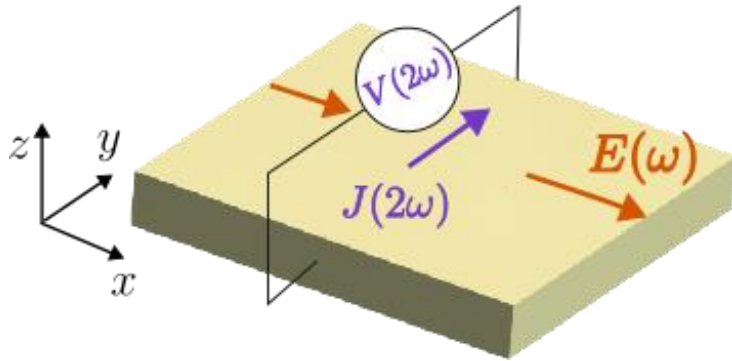
1982: Fractional Quantum Hall

[Adapted from C. Chang et al. J. Phys. Cond. Matt. (2016), R. Samajdar et al. PRB (2019) and Z.Z. Du et al. Nat. Phys. (2021)]

The non-linear anomalous Hall effects

- Hall current oscillates at a different frequency than the electric field

This talk: **second-order anomalous Hall effect**



$$J_y(\Sigma) = \sigma_{yxx}(\omega_1, \omega_2) E_x(\omega_1) E_x(\omega_2)$$

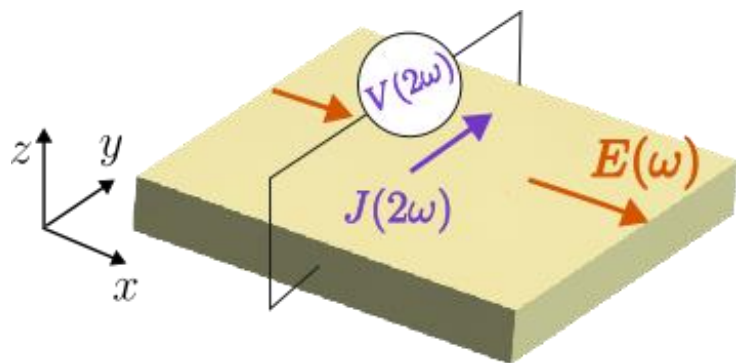
$\Sigma = \omega_1 + \omega_2$

antisymmetric in y and x

The non-linear anomalous Hall effects

- Hall current oscillates at a different frequency than the electric field

This talk: **second-order anomalous Hall effect**



$$J_y(\Sigma) = \sigma_{yxx}(\omega_1, \omega_2) E_x(\omega_1) E_x(\omega_2)$$

$$\Sigma = \omega_1 + \omega_2$$

antisymmetric in y and x

Two possibilities:

$$a) \omega_1 = \omega_2 \Rightarrow \Sigma = 2\omega$$

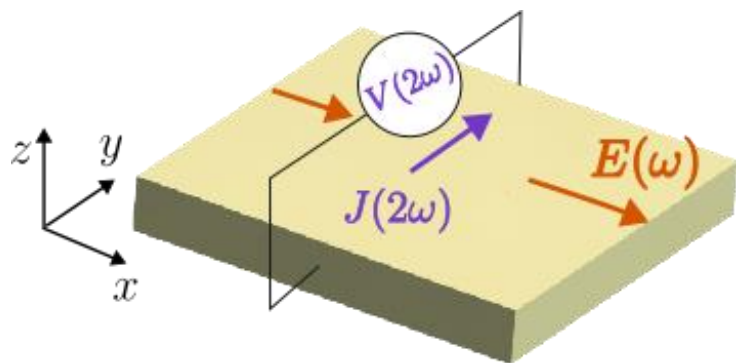
$$b) \omega_2 = -\omega_1 \Rightarrow \Sigma = 0$$

- Can happen even in the **presence of time-reversal symmetry**
- Require **inversion symmetry breaking**

The non-linear anomalous Hall effects

- Hall current oscillates at a different frequency than the electric field

This talk: **second-order anomalous Hall effect**



$$J_y(\Sigma) = \sigma_{yxx}(\omega_1, \omega_2) E_x(\omega_1) E_x(\omega_2)$$

$\Sigma = \omega_1 + \omega_2$ antisymmetric in y and x

Two possibilities:

a) $\omega_1 = \omega_2 \Rightarrow \Sigma = 2\omega$

b) $\omega_2 = -\omega_1 \Rightarrow \Sigma = 0$

- Can happen even in the **presence of time-reversal symmetry**
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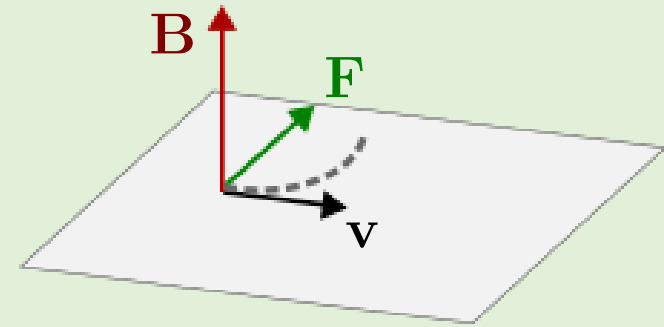
What is the microscopic mechanism?

Theory of the linear Hall effects

Normal Hall

Lorentz force

$$\mathbf{F} = -e\mathbf{v} \times \mathbf{B}$$

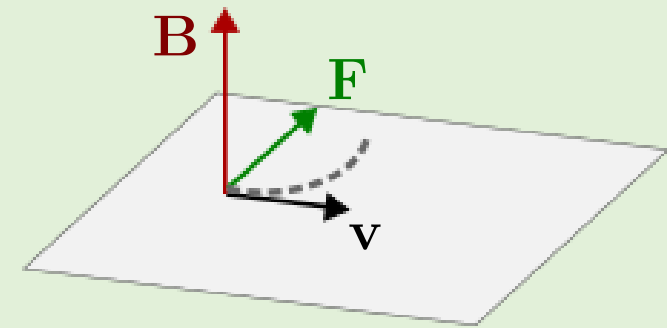


Theory of the linear Hall effects

Normal Hall

Lorentz force

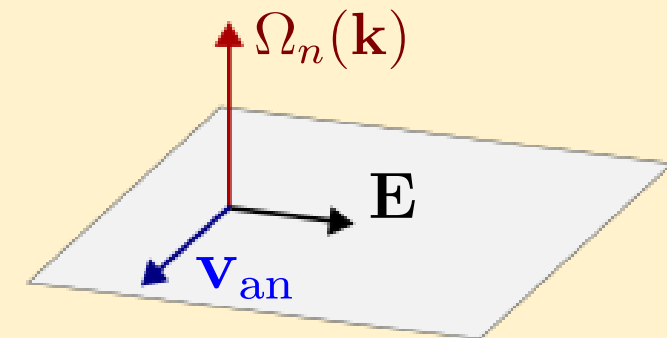
$$\mathbf{F} = -e\mathbf{v} \times \mathbf{B}$$



(Linear) anomalous Hall

Extrinsic: disorder $\rightarrow$ depend on electron lifetime τ

Intrinsic: anomalous velocity $\rightarrow$ independent of τ



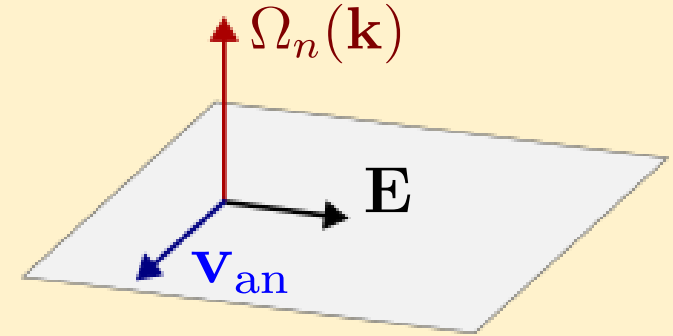
Cannot be explained by band structure alone!

Theory of the linear Hall effects

(Linear) anomalous Hall

Intrinsic: anomalous velocity $\rightarrow$ independent of τ

$$\mathbf{v}_{\text{an}} = \frac{e}{\hbar} \mathbf{E} \times \boldsymbol{\Omega}_n(\mathbf{k})$$

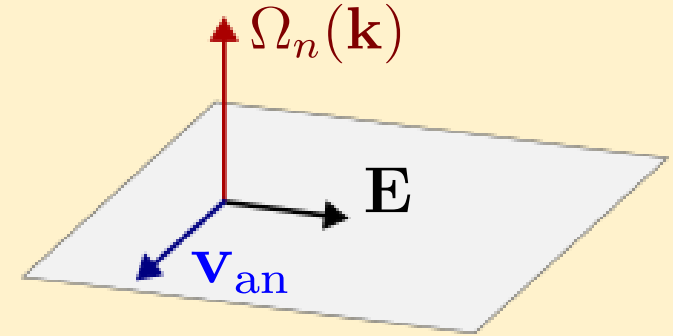


Theory of the linear Hall effects

(Linear) anomalous Hall

Intrinsic: anomalous velocity $\rightarrow$ independent of τ

$$\mathbf{v}_{\text{an}} = \frac{e}{\hbar} \mathbf{E} \times \Omega_n(\mathbf{k}) \leftarrow \text{Berry curvature!}$$



Electrons in solids:

$$\psi_{n,\mathbf{k}}(\mathbf{r}) = e^{i\mathbf{k}\cdot\mathbf{r}} \langle \mathbf{r} | u_{n,\mathbf{k}} \rangle$$

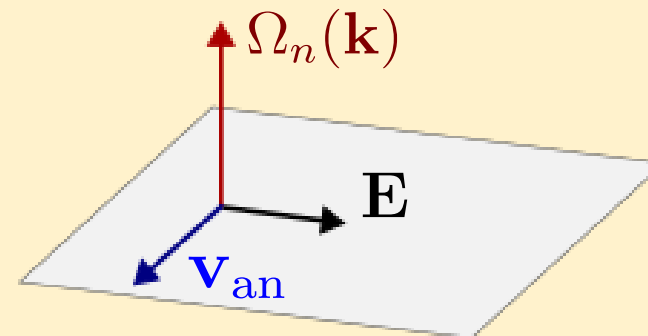
$$\Omega_n(\mathbf{k}) = \nabla_{\mathbf{k}} \times \langle u_{n,\mathbf{k}} | \nabla_{\mathbf{k}} u_{n,\mathbf{k}} \rangle$$

Theory of the linear Hall effects

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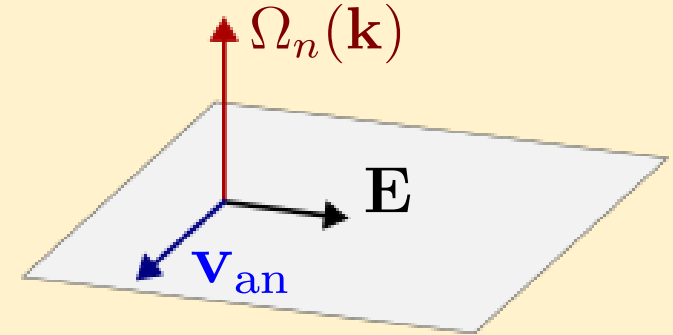
$$\Omega_n(\mathbf{k}) = \nabla_{\mathbf{k}} \times \langle u_{n,\mathbf{k}} | \nabla_{\mathbf{k}} u_{n,\mathbf{k}} \rangle$$

Theory of the linear Hall effects

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Electric current:

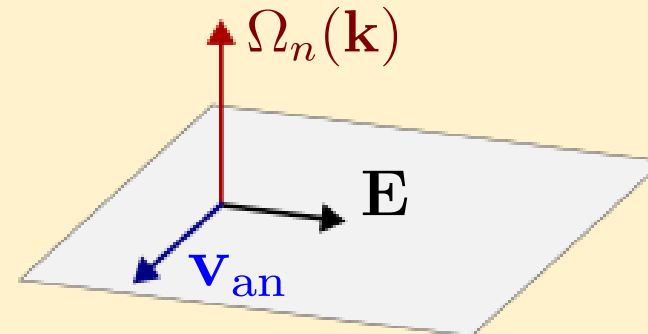
$$\mathbf{J} = -e \int_{\mathbf{k}} f_0(\mathbf{k}) \mathbf{v}_{\text{an}} \quad \longrightarrow \quad \sigma_{yx} = \frac{e^2}{\hbar} \sum_{n \in \text{occ}} \int \frac{d^d k}{(2\pi)^d} f_0(\mathbf{k}) \Omega_n^z(\mathbf{k})$$

Theory of the linear Hall effects

(Linear) anomalous Hall

Intrinsic: anomalous velocity $\rightarrow$ independent of τ

$$\mathbf{v}_{\text{an}} = \frac{e}{\hbar} \mathbf{E} \times \Omega_n(\mathbf{k}) \leftarrow \text{Berry curvature!}$$



Electrons in solids:

$$\psi_{n,\mathbf{k}}(\mathbf{r}) = e^{i\mathbf{k}\cdot\mathbf{r}} \langle \mathbf{r} | u_{n,\mathbf{k}} \rangle \leftarrow \text{cell periodic}$$

$$\Omega_n(\mathbf{k}) = \nabla_{\mathbf{k}} \times \langle u_{n,\mathbf{k}} | \nabla_{\mathbf{k}} u_{n,\mathbf{k}} \rangle$$

$$\sigma_{yx} = \frac{e^2}{\hbar} \sum_{n \in \text{occ}} \int \frac{d^d k}{(2\pi)^d} f_0(\mathbf{k}) \Omega_n^z(\mathbf{k})$$

Time reversal ($\mathcal{T}$):

$$\Omega_n(\mathbf{k}) \xrightarrow{\mathcal{T}} -\Omega_n(-\mathbf{k})$$

$$f_0(\mathbf{k}) \xrightarrow{\mathcal{T}} f_0(-\mathbf{k})$$

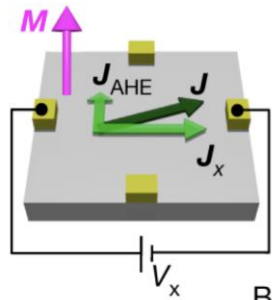
Requires $\mathcal{T}$ breaking!

Non-linear Hall: beyond the Berry curvature

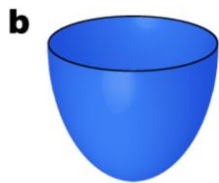
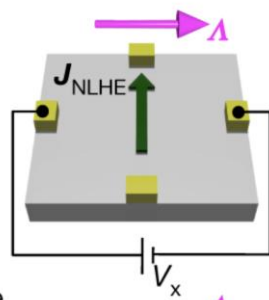
- Extrinsic contributions to the non-linear Hall effect also involves the Berry curvature

$$\chi_{abc} = \varepsilon_{adc} \frac{e^3 \tau}{2(1 + i\omega\tau)} \int_k \boxed{(\partial_b f_0) \Omega_d}.$$

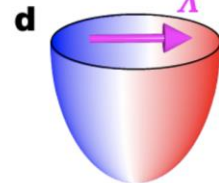
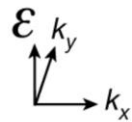
a Anomalous Hall effect



c Nonlinear Hall effect



Berry curvature
- +



Berry curvature
dipole

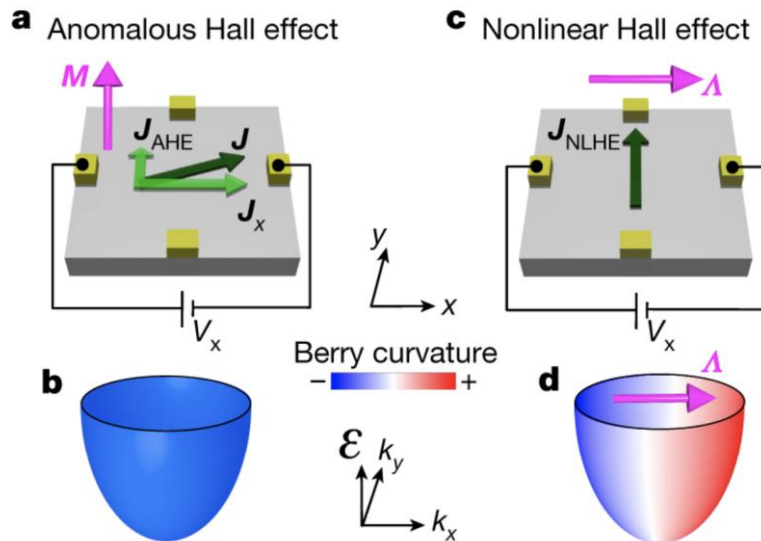
[Sodemann, Fu (2014; Ma *et al.* (2018); Kang *et al.* (2018)]

Non-linear Hall: beyond the Berry curvature

- Extrinsic contributions to the non-linear Hall effect also involves the Berry curvature

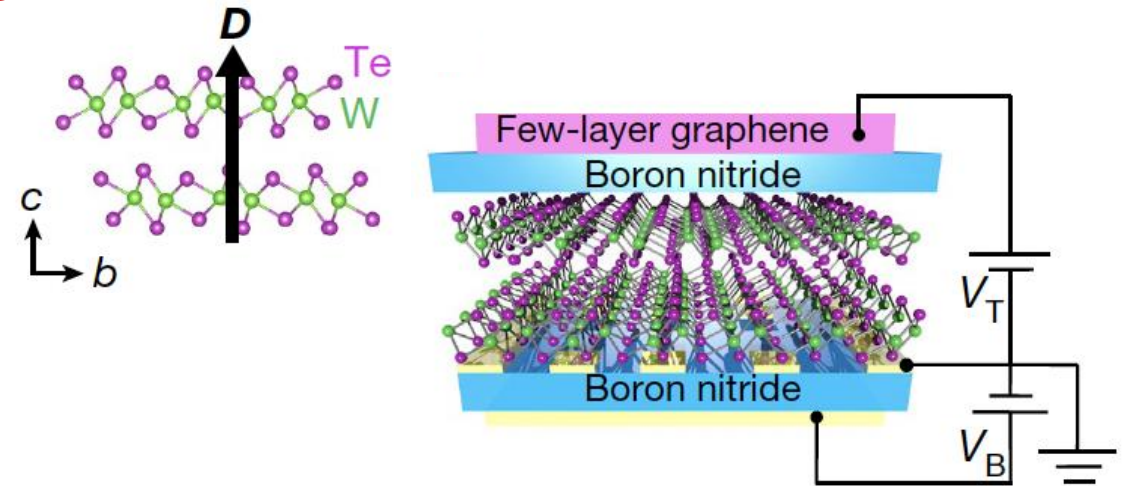
$$\chi_{abc} = \varepsilon_{adc} \frac{e^3 \tau}{2(1 + i\omega\tau)} \int_k (\partial_b f_0) \Omega_d.$$

Berry curvature
dipole



Observed in bilayer WTe_2

From Ma *et al.* (2018):



[Sodemann, Fu (2014); Ma *et al.* (2018); Kang *et al.* (2018)]

- Intrinsic second-order Hall effect is generated by dipoles of the quantum metric

The quantum geometry of the electrons

- Quantum geometric tensor: geometric properties of the electron **wave functions**

$$\mathcal{Q}_{\mu\nu}^{(n)}(\mathbf{k}) = \langle \partial_\mu u_n | \partial_\nu u_n \rangle - \langle \partial_\mu u_n | u_n \rangle \langle u_n | \partial_\nu u_n \rangle = - \sum_{m \neq n} \mathcal{A}_{mn}^{(\mu)}(\mathbf{k}) \mathcal{A}_{nm}^{(\nu)}(\mathbf{k})$$


$$\mathcal{A}_{mn}^{(\mu)} = i \langle u_{m,\mathbf{k}} | \partial_\mu u_{n,\mathbf{k}} \rangle$$

Non-Abelian Berry connection

The quantum geometry of the electrons

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$$\text{Im} \mathcal{Q}_{\mu\nu}^{(n)}(\mathbf{k}) = -\frac{1}{2} \Omega_{\mu\nu}(\mathbf{k}) \quad \longleftarrow \text{Berry curvature}$$

$$\mathcal{A}_{mn}^{(\mu)} = i \langle u_{m,\mathbf{k}} | \partial_\mu u_{n,\mathbf{k}} \rangle$$

Non-Abelian Berry connection

The quantum geometry of the electrons

- Quantum geometric tensor: geometric properties of the electron **wave functions**

$$\mathcal{Q}_{\mu\nu}^{(n)}(\mathbf{k}) = \langle \partial_\mu u_n | \partial_\nu u_n \rangle - \langle \partial_\mu u_n | u_n \rangle \langle u_n | \partial_\nu u_n \rangle = - \sum_{m \neq n} \mathcal{A}_{mn}^{(\mu)}(\mathbf{k}) \mathcal{A}_{nm}^{(\nu)}(\mathbf{k})$$

$$\text{Im} \mathcal{Q}_{\mu\nu}^{(n)}(\mathbf{k}) = -\frac{1}{2} \Omega_{\mu\nu}(\mathbf{k}) \quad \longleftarrow \text{Berry curvature}$$

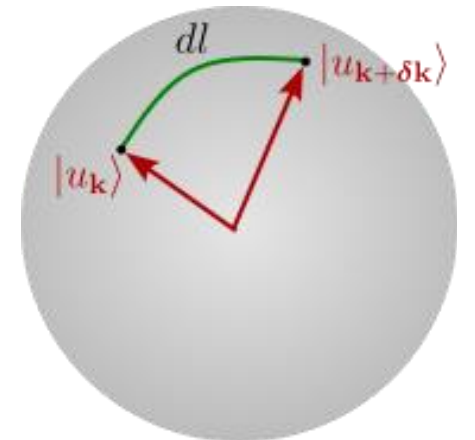
$$\mathcal{A}_{mn}^{(\mu)} = i \langle u_{m,\mathbf{k}} | \partial_\mu u_{n,\mathbf{k}} \rangle$$

Non-Abelian Berry connection

$$\text{Re} \mathcal{Q}_{\mu\nu}^{(n)}(\mathbf{k}) = g_{\mu\nu}(\mathbf{k})$$

$\longleftarrow$ **Quantum metric**
Distance between quantum states

$$dl^2 = ||u_{\mathbf{k}+\delta\mathbf{k}}\rangle - |u_{\mathbf{k}}\rangle|^2$$

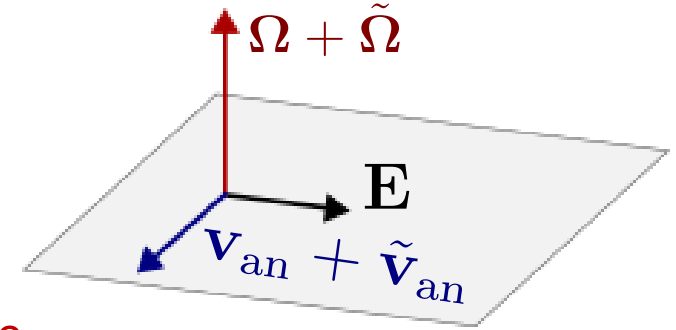


Theory of the intrinsic non-linear Hall effect: beyond Berry curvature

- Semiclassical description (**second order** in $\mathbf{E}$, with $\mathbf{B} = 0$) [Y. Gao et al. PRL 112 (2014)]

$$\begin{cases} \dot{\mathbf{r}} = \frac{1}{\hbar} \nabla_{\mathbf{k}} \tilde{\mathcal{E}}_{n,\mathbf{k}} - \dot{\mathbf{k}} \times \Omega_n(\mathbf{k}) - \dot{\mathbf{k}} \times \left(\nabla_{\mathbf{k}} \times \overset{\leftrightarrow}{G}_n \mathbf{E} \right) \\ \dot{\mathbf{k}} = -\frac{e}{\hbar} \mathbf{E} \end{cases}$$

field correction to the
anomalous velocity ($\tilde{v}_{an}$)

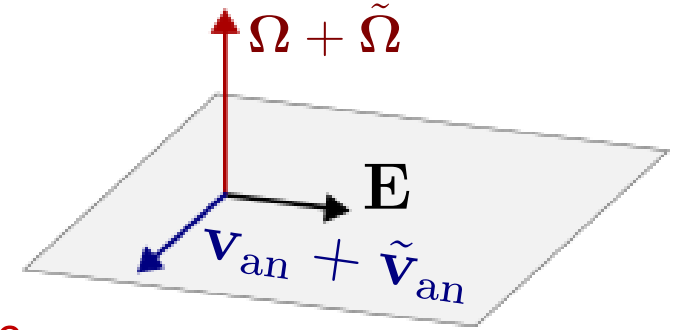


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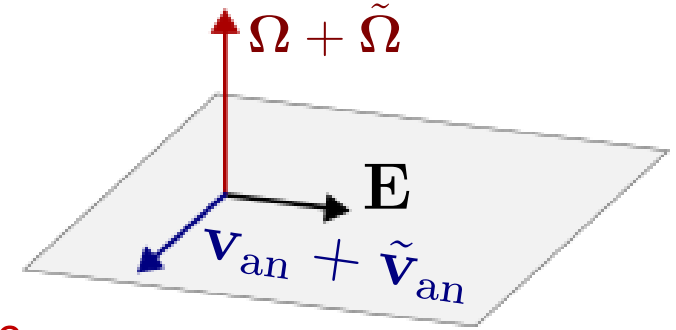


For $E \hat{x}$: $\tilde{v}_{an,y} = \frac{e}{\hbar} (\partial_x G_{yx} - \partial_y G_{xx})$

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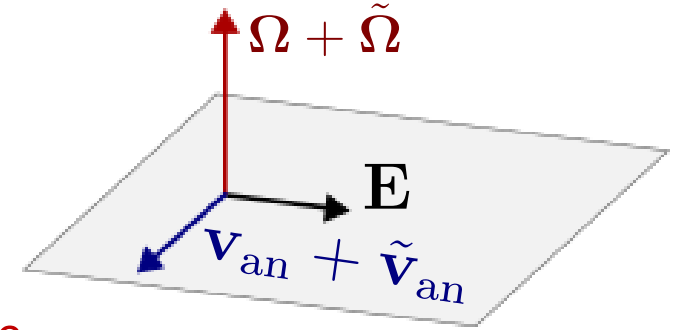
$$G_{n,\mu\nu}(\mathbf{k}) = 2\text{Re} \sum_{m \neq n} \frac{\mathcal{A}_{mn}^{(\mu)}(\mathbf{k}) \mathcal{A}_{nm}^{(\nu)}(\mathbf{k})}{\varepsilon_n(\mathbf{k}) - \varepsilon_m(\mathbf{k})}$$

← Berry curvature polarizability

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$$\mathcal{Q}_{\mu\nu}^{(n)}(\mathbf{k}) = \langle \partial_{\mu} u_n | \partial_{\nu} u_n \rangle - \langle \partial_{\mu} u_n | u_n \rangle \langle u_n | \partial_{\nu} u_n \rangle = - \sum_{m \neq n} \mathcal{A}_{mn}^{(\mu)}(\mathbf{k}) \mathcal{A}_{nm}^{(\nu)}(\mathbf{k})$$

Theory of the intrinsic non-linear Hall effect

- From the field correction to the anomalous velocity:

$$\sigma_{yxx} = 2e^3 \sum_n \int \frac{d^d k}{(2\pi)^d} \frac{v_y^n g_{xx}^{(n)}(\mathbf{k}) - v_x^n g_{yx}^{(n)}(\mathbf{k})}{\varepsilon_{n,\mathbf{k}} - \varepsilon_{\bar{n},\mathbf{k}}} \delta(\varepsilon_{n,\mathbf{k}} - \varepsilon_F) + \text{AIC}$$

Antisymmetric:

$$\sigma_{yxx} = -\sigma_{xyx}$$

Theory of the intrinsic non-linear Hall effect

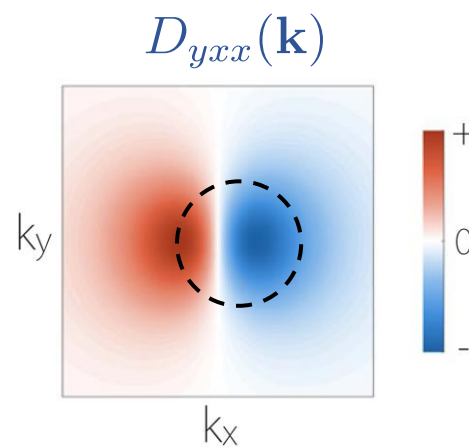
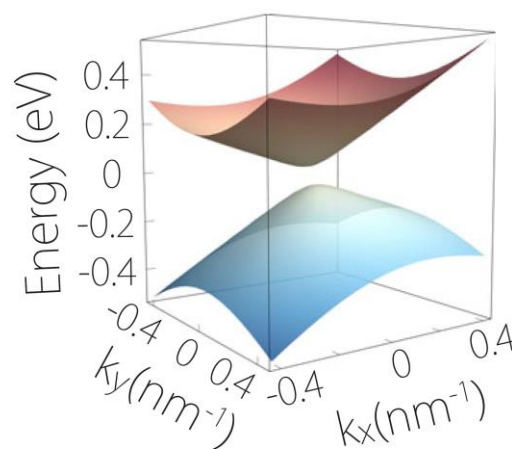
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Quantum metric dipole: $D_{yxx}(\mathbf{k})$



[Adapted from Liu et al. PRL 127 (2021)]

Theory of the intrinsic non-linear Hall effect

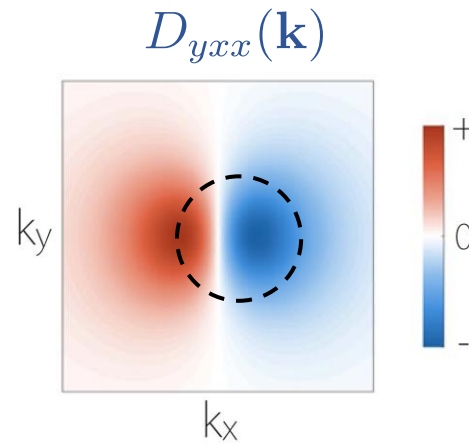
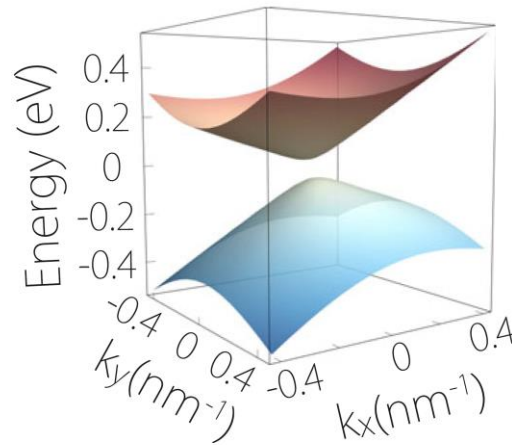
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Additional interband contributions

[Adapted from Liu et al. PRL 127 (2021)]

Symmetry considerations

- What about the original anomalous velocity contribution?

$$\dot{\mathbf{r}} = \frac{1}{\hbar} \nabla_{\mathbf{k}} \tilde{\varepsilon}_{n,\mathbf{k}} - \dot{\mathbf{k}} \times \Omega_n(\mathbf{k}) - \dot{\mathbf{k}} \times \left(\nabla_{\mathbf{k}} \times \overset{\leftrightarrow}{G}_n \mathbf{E} \right)$$

- Quantum metric Hall effect **dominates** in $\mathcal{PT}$ symmetric materials

Time-reversal ($\mathcal{T}$): $\Omega_n(\mathbf{k}) \xrightarrow{\mathcal{T}} -\Omega_n(-\mathbf{k})$

Inversion ($\mathcal{P}$): $\Omega_n(\mathbf{k}) \xrightarrow{\mathcal{P}} \Omega_n(-\mathbf{k})$



$$\Omega_n(\mathbf{k}) \overset{\mathcal{PT}}{=} 0$$

[Y. Gao et al. PRL 112 (2014), C. Wang et al. PRL 127 (2021)]

First observation in a heterostructure of MnBi_2Te_4 and BP

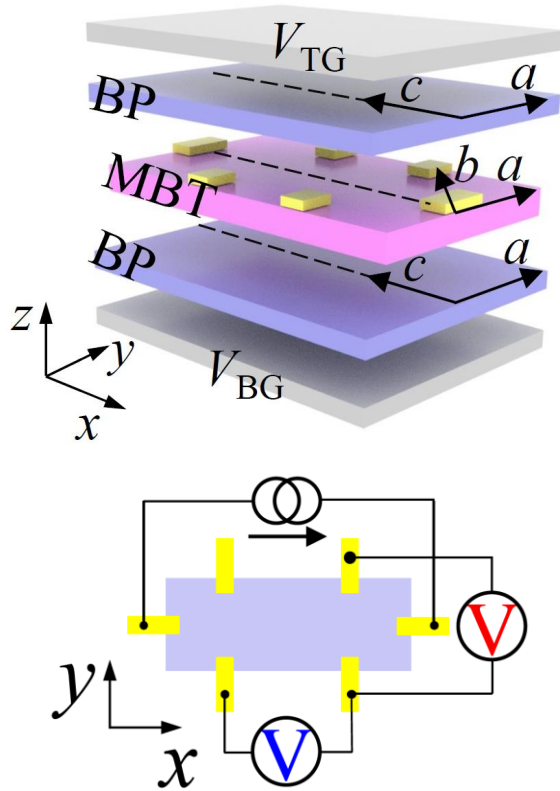
Experimentally measured anomalous Hall effect



Suyang Xu
Harvard

- Material: heterostructure composed by MnBi_2Te_4 (MBT) and black phosphorus (BP)

SETUP:



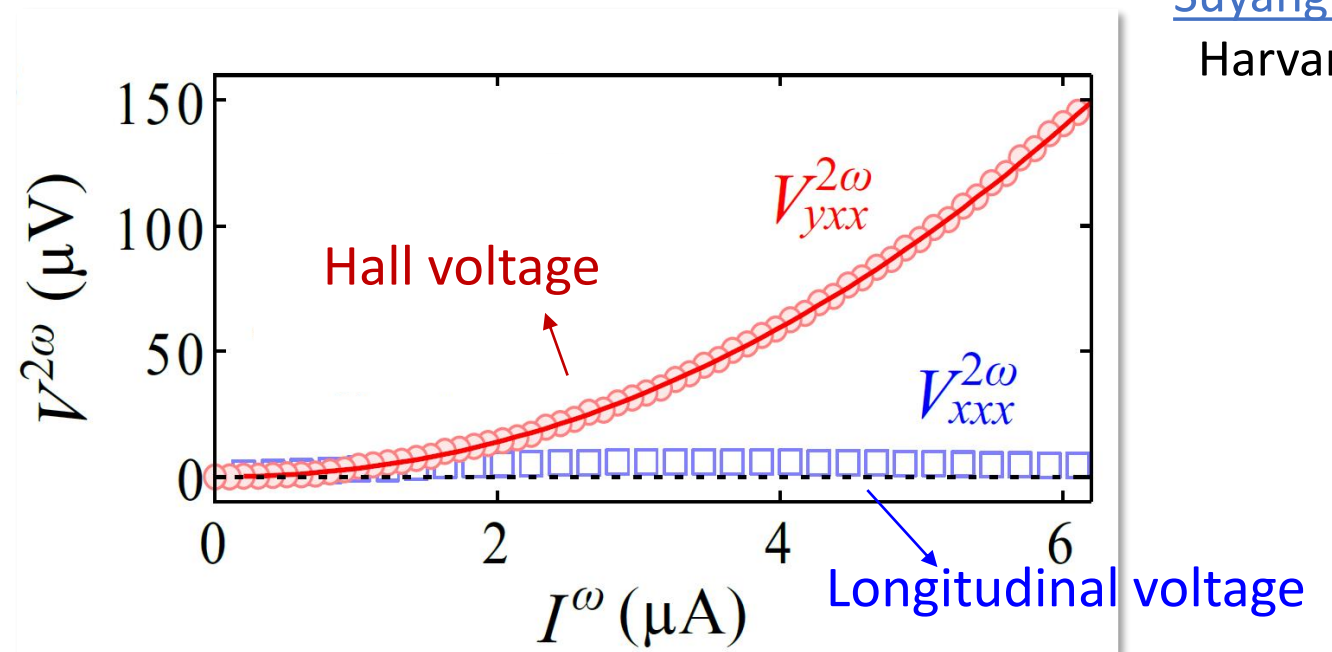
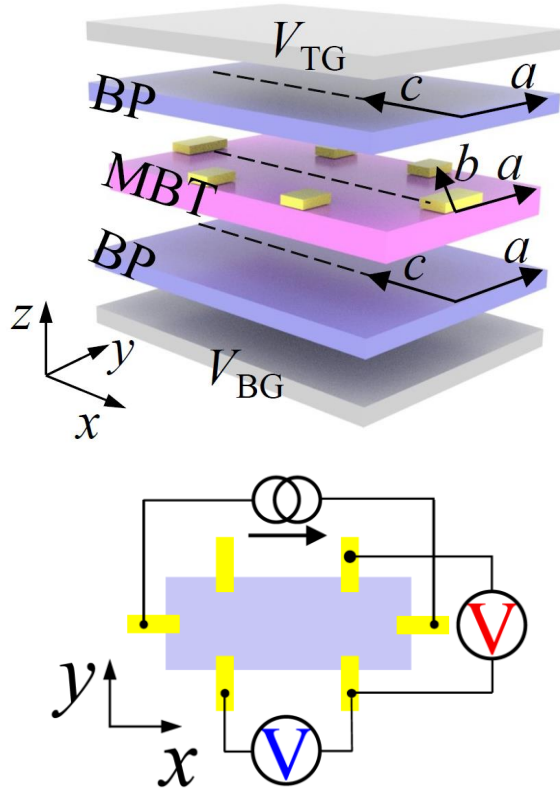
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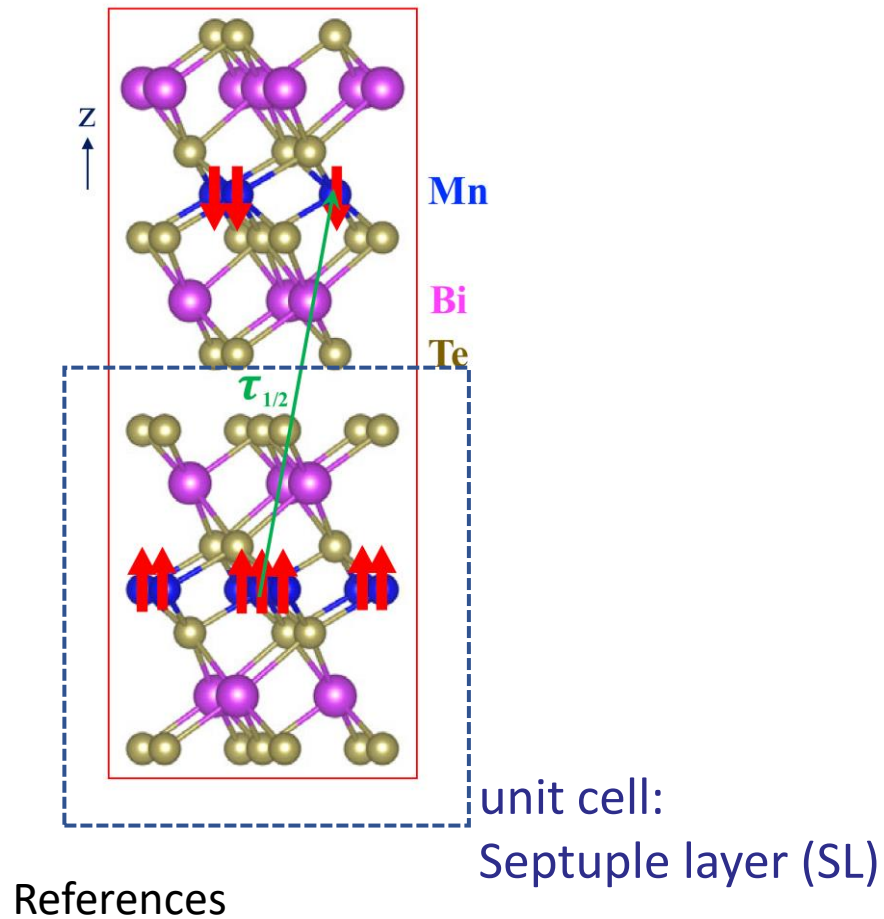
SETUP:



→ Dominance of the Hall response

Properties of MnBi_2Te_4

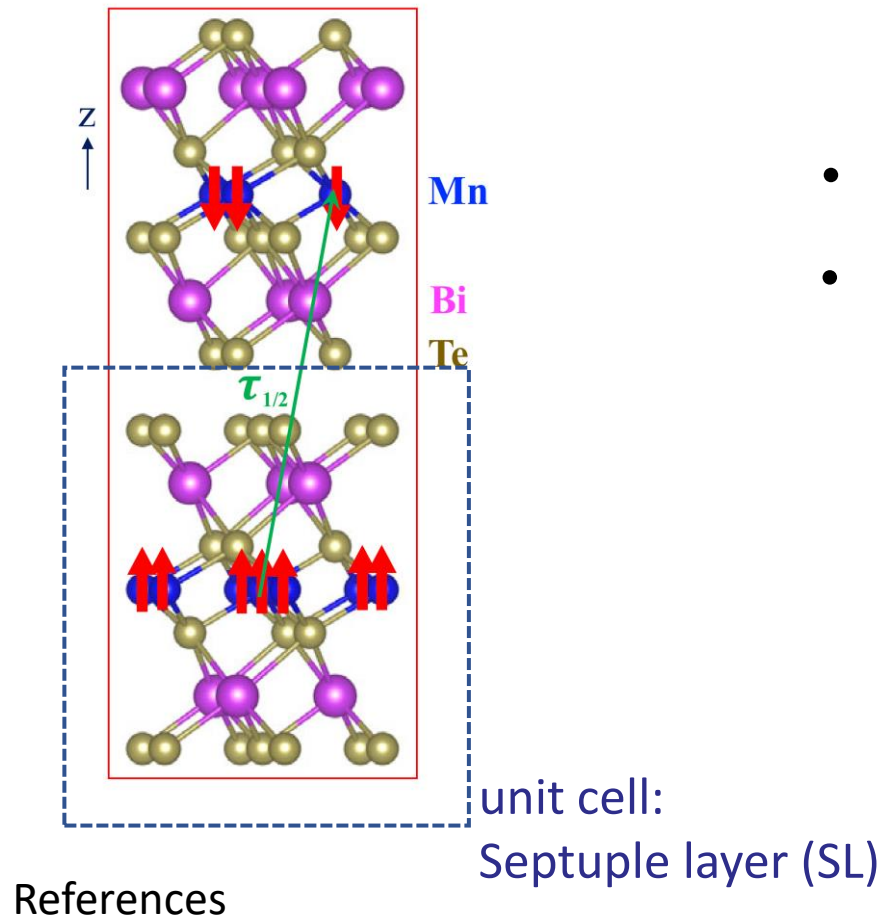
CRYSTAL STRUCTURE



- Crystal space group: $R\bar{3}m \rightarrow \begin{cases} C_{3z} \checkmark \\ \mathcal{P} \checkmark \text{ (spatial inversion)} \end{cases}$

Properties of MnBi₂Te₄

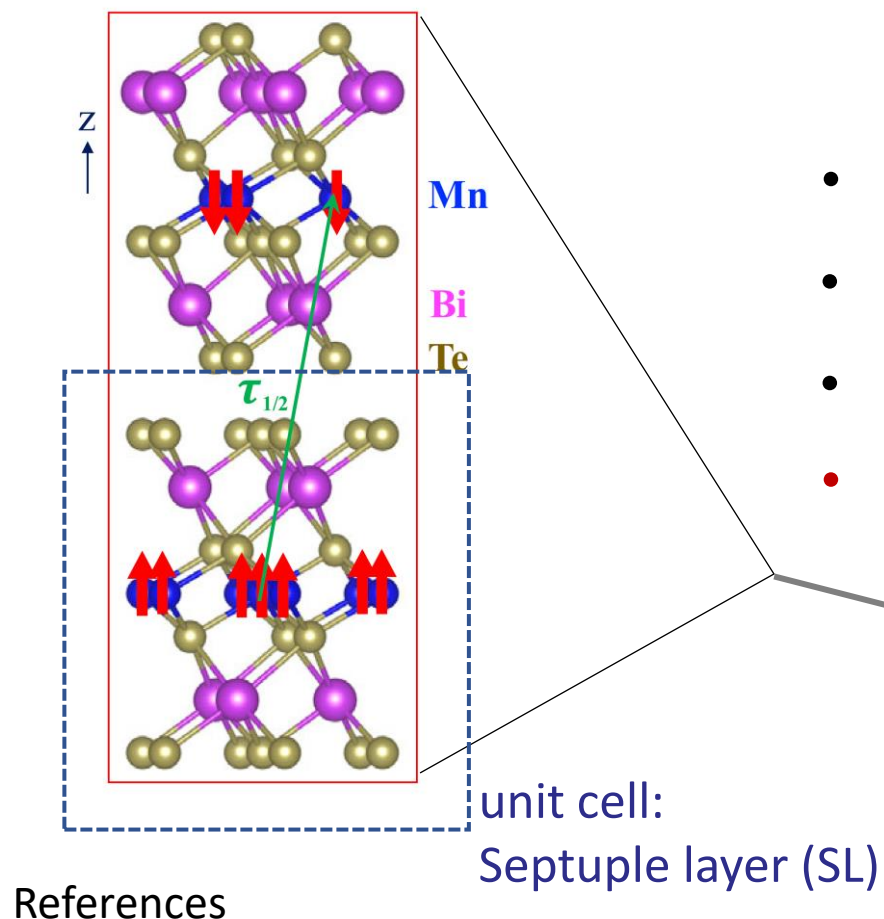
CRYSTAL STRUCTURE



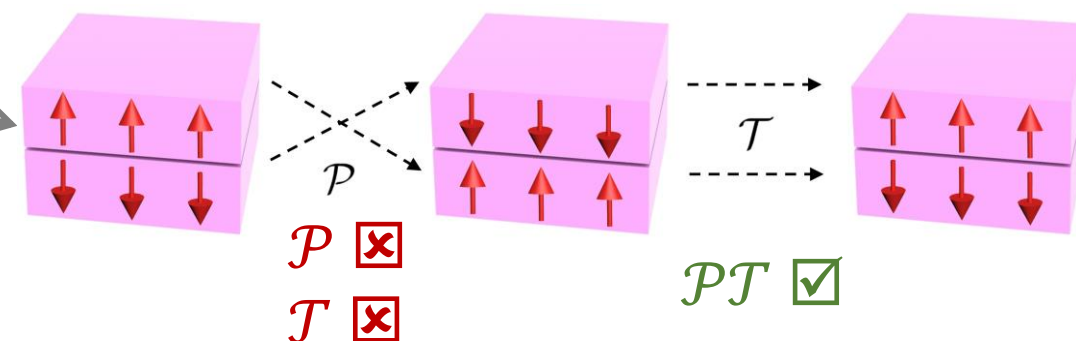
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Properties of MnBi_2Te_4

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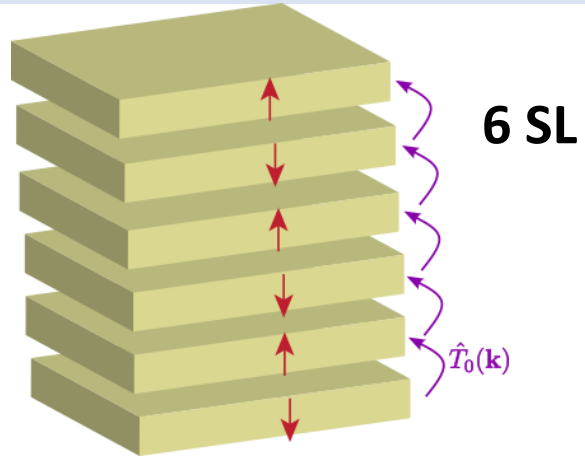


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- Ground state is AFM
- SLs coupling is van der Waals type
- Even layer structures:



$\mathcal{PT}$ symmetric AFM $\Rightarrow \Omega(\mathbf{k}) = 0$

Fermi surface and quantum metric dipole in the 6SL MBT



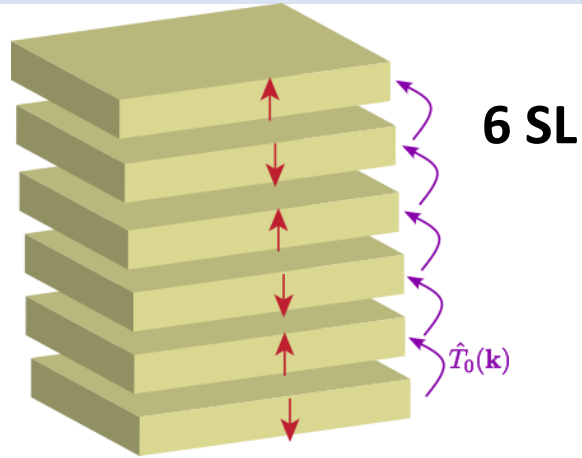
- Low energy physics dominated by p_z orbitals of Bi and Te atoms

Each SL: k.p model around the center of BZ

[B. Lian et al. PRL 124 (2020)]

$$\hat{h}_s(\mathbf{k}) = \hat{h}_N(\mathbf{k}) + (-1)^s \gamma_{af} \hat{h}_M(\mathbf{k})$$

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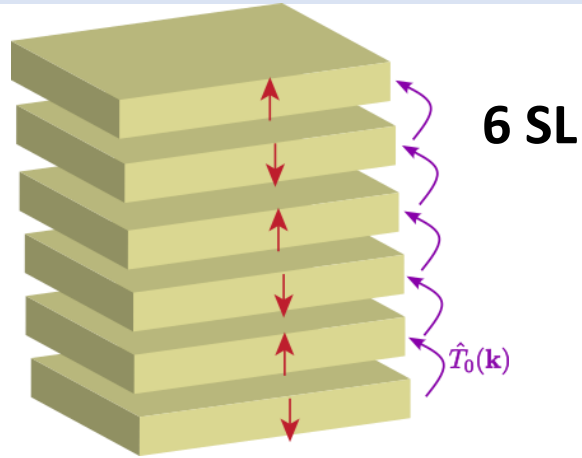
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$$\hat{h}_\zeta(\mathbf{k}) = \underbrace{\hat{h}_N(\mathbf{k})}_{\text{Normal state}} + (-1)^\zeta \gamma_{af} \underbrace{\hat{h}_M(\mathbf{k})}_{\text{Ferromagnetic ordering in each SL}}$$

Normal state
(consistent with $R\bar{3}m$)

Ferromagnetic
ordering in each SL

Fermi surface and quantum metric dipole in the 6SL MBT



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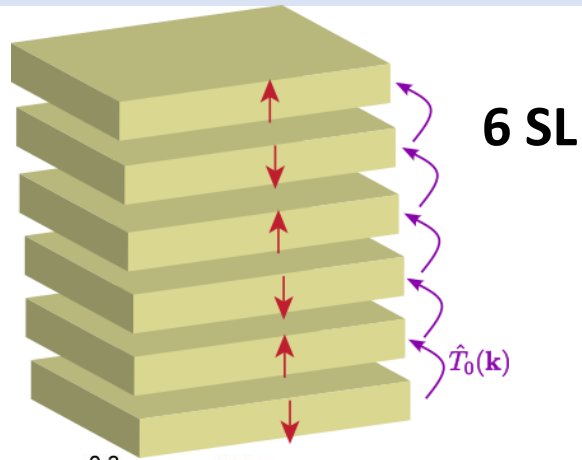
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Inter-SL hopping: $T_0(\mathbf{k})$

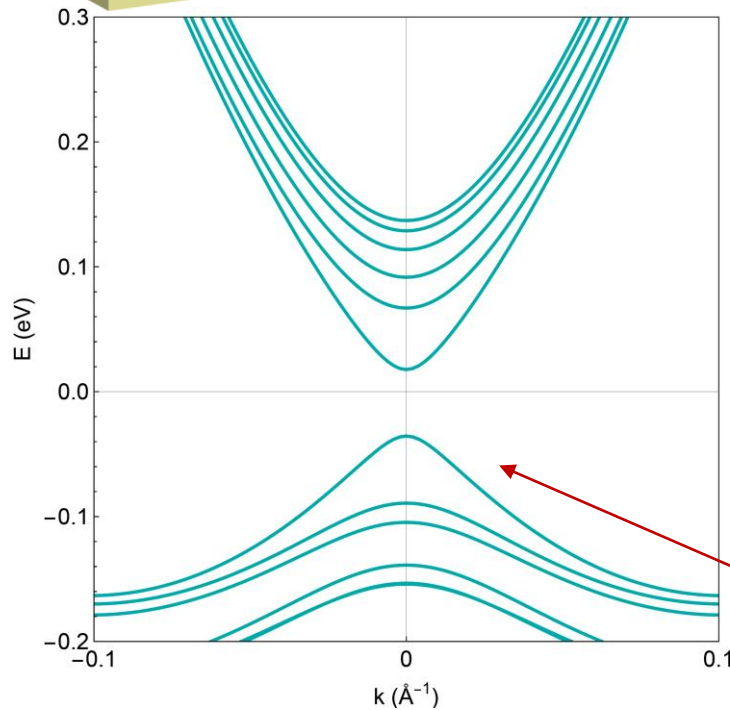
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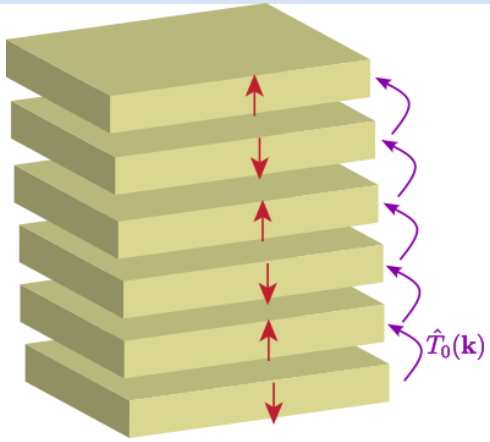


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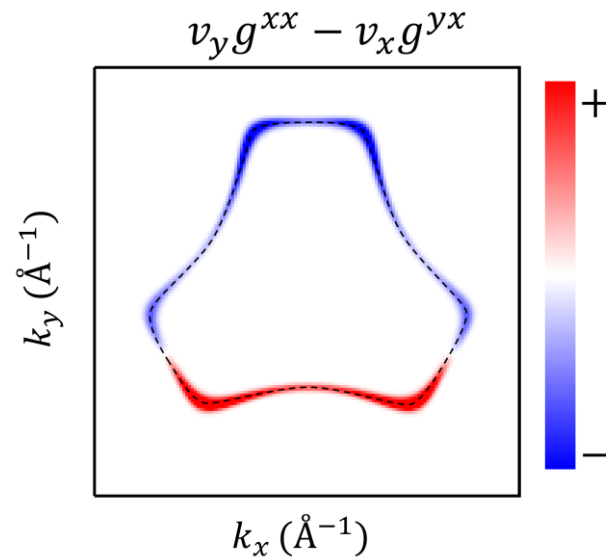
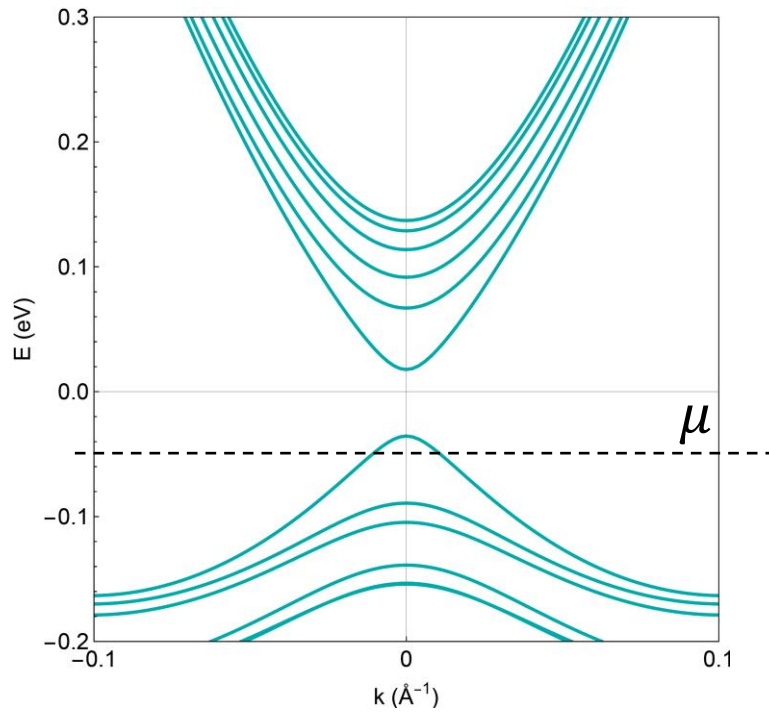
Large quantum metric!

Fermi surface and quantum metric dipole in the 6SL MBT

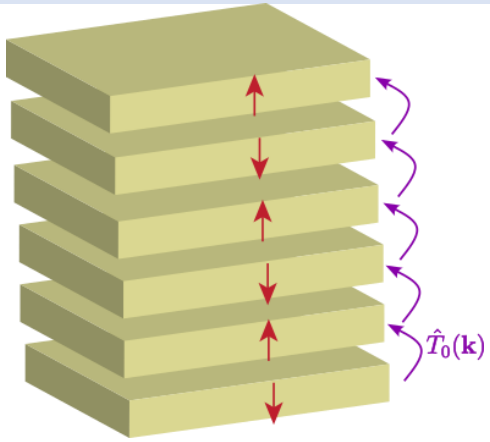


For $\mu = -50$ meV :

Quantum metric dipole:

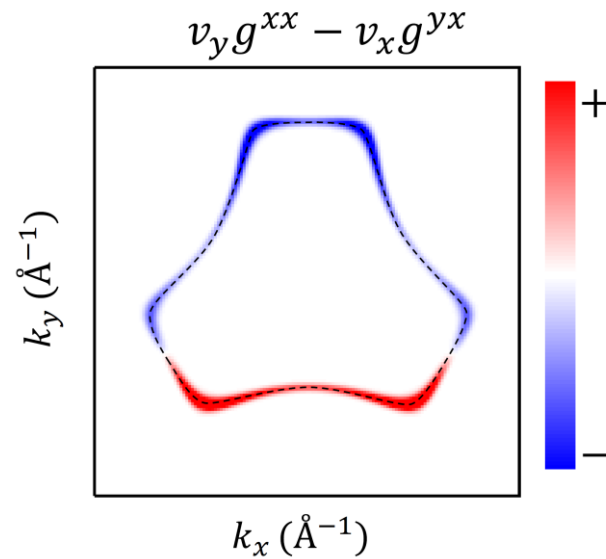
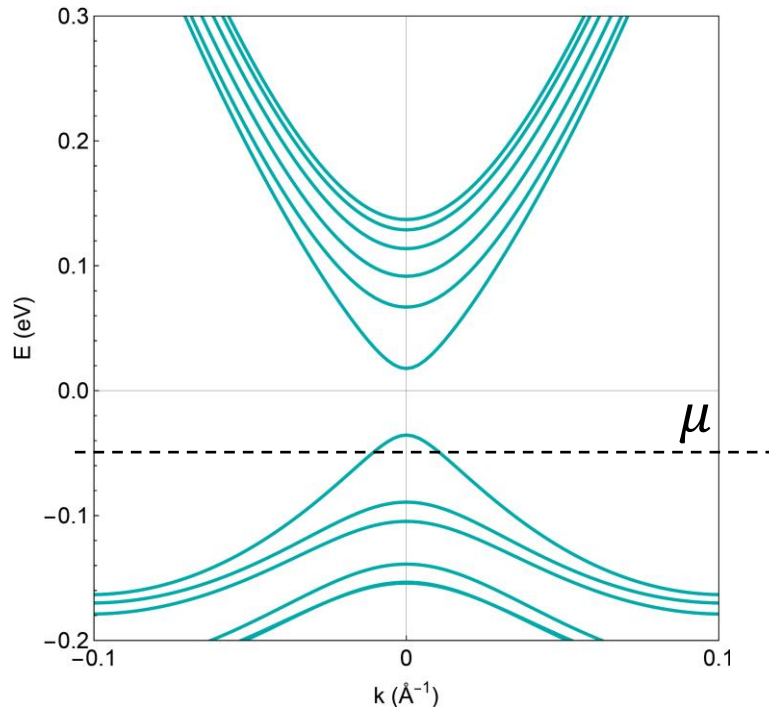


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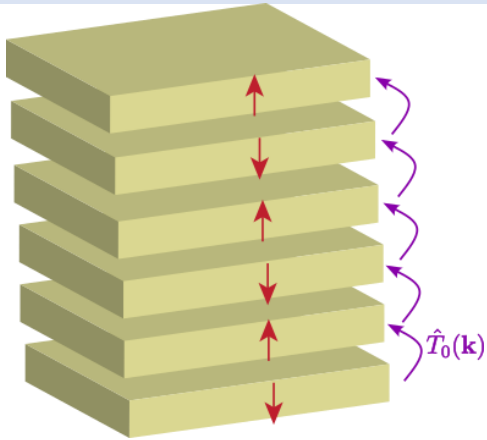
Quantum metric dipole:



$$\xrightarrow{C_{3z}} \int_{\text{FS}} d\mathbf{k} [v_y g_{xx} - v_x g_{yx}] = 0$$

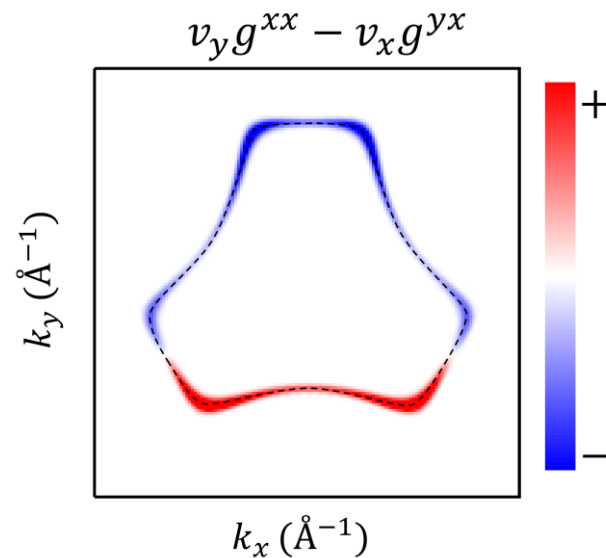
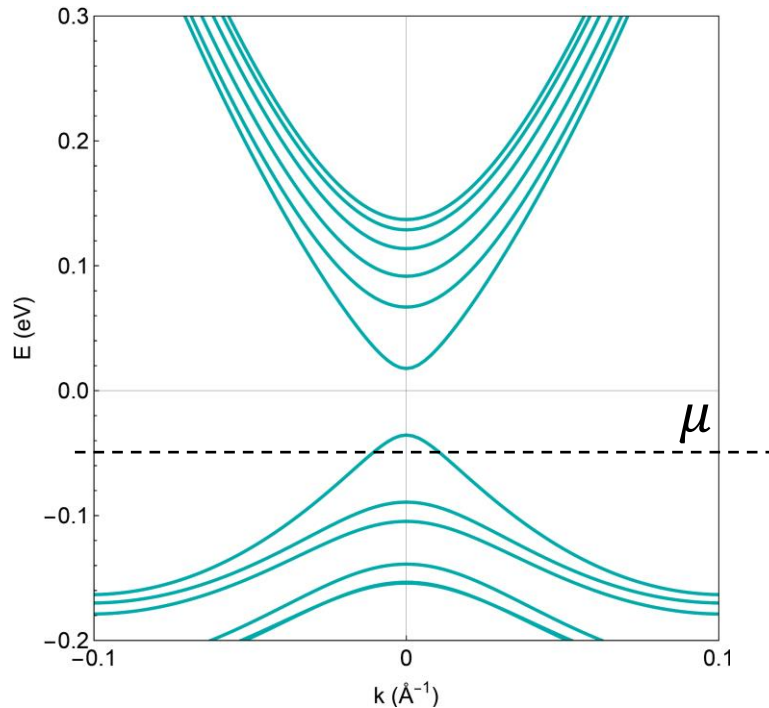
No quantum metric Hall effect

Fermi surface and quantum metric dipole in the 6SL MBT



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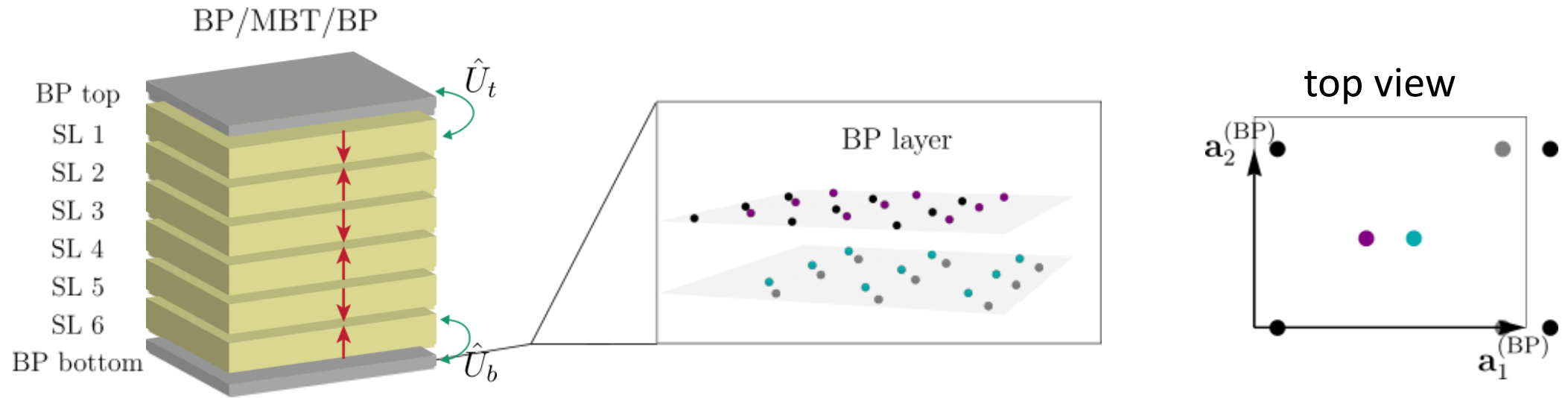


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No quantum metric Hall effect

We need to break C_{3z} symmetry and keep $\mathcal{PT}$...
How?

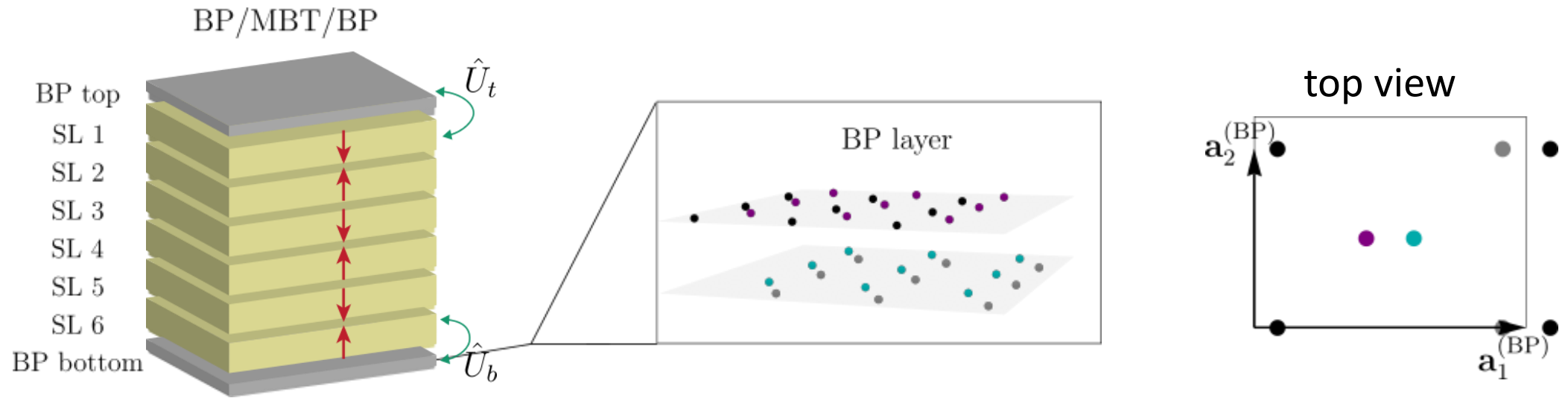
Black phosphorus (BP) promotes the needed C_{3z} breaking



- Low energy physics: tight-binding dominated by p_z orbitals of P atoms

[Ezawa et al. NJP (2014)
Rudenko et al. PRB (2015)]

Black phosphorus (BP) promotes the needed C_{3z} breaking



- Low energy physics: tight-binding dominated by p_z orbitals of P atoms [Ezawa et al. NJP (2014) Rudenko et al. PRB (2015)]

- BP tetragonal lattice breaks C_{3z}

Sources of C_{3z} breaking:

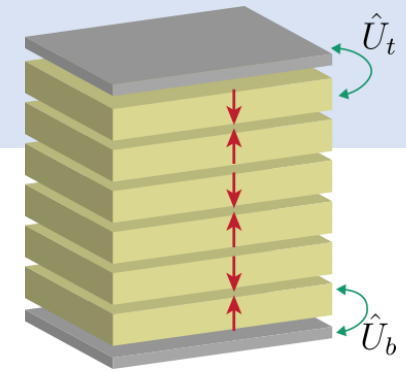
a) Hybridization of BP and MBT bands

Next-neighbor interlayer hopping: $\hat{U}_b$ and $\hat{U}_t$

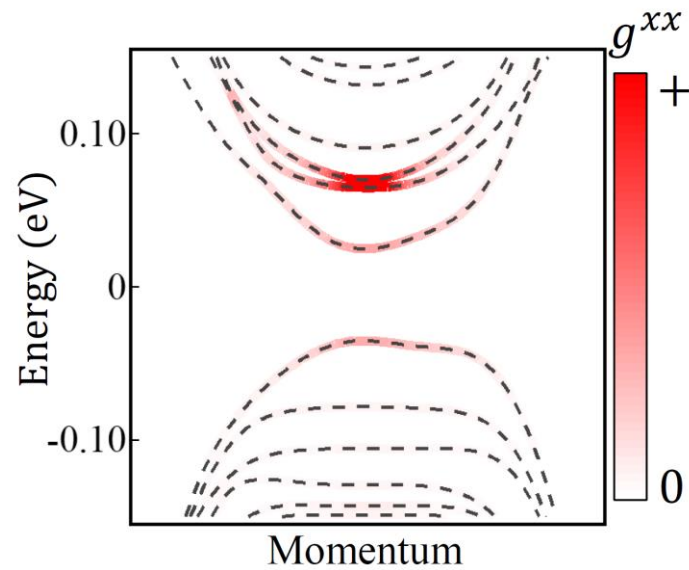
b) Lattice mismatch $\Rightarrow$ strain

[Gao, Liu, Qiu, Gosh, Trevisan et al., Science (2023)]

The BP/MBT/BP heterostructure: results from theoretical modeling

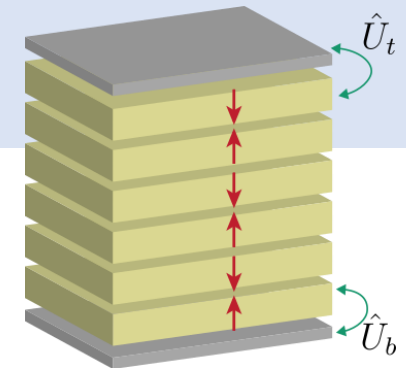


Band structure:

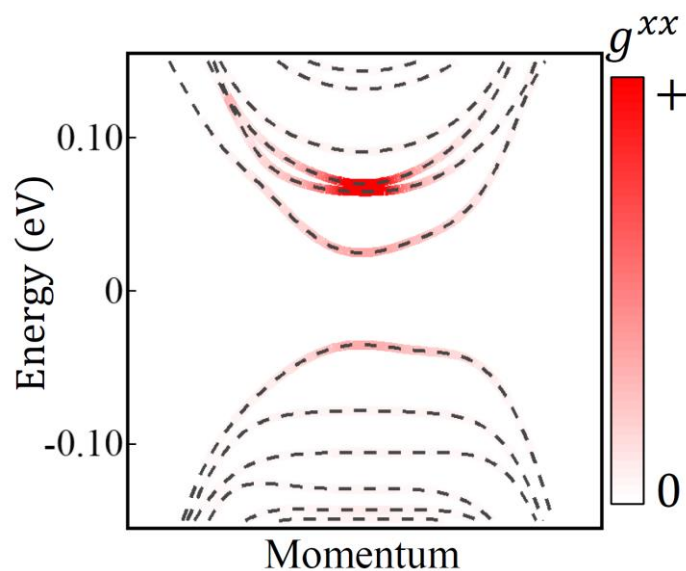


Large quantum metric
at small band gaps

The BP/MBT/BP heterostructure: results from theoretical modeling

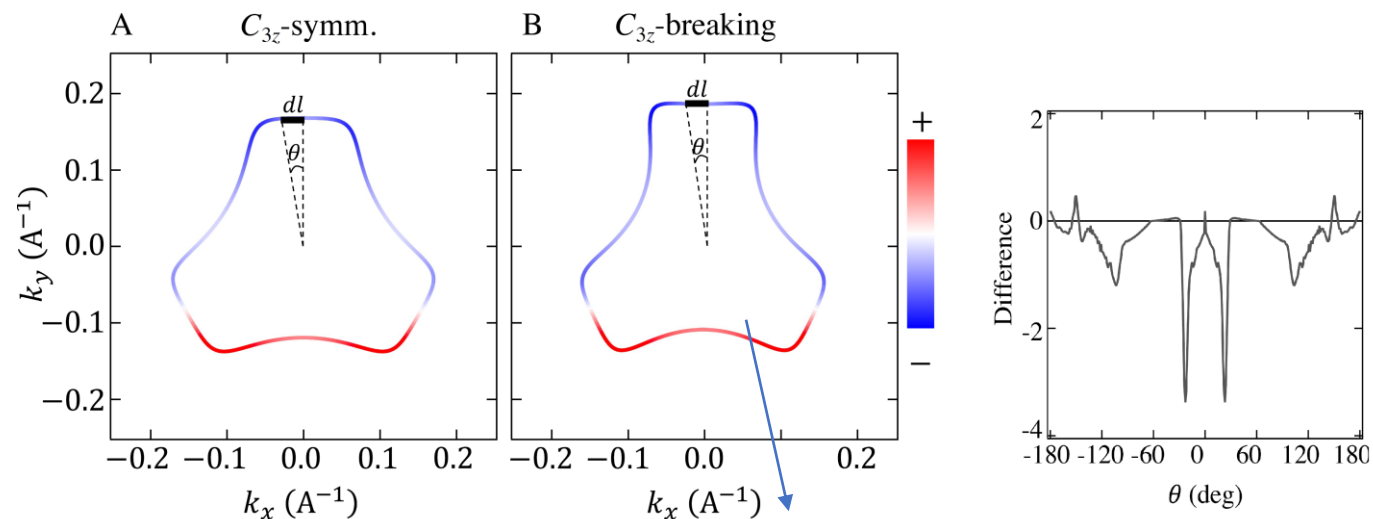


Band structure:



Quantum metric dipole:

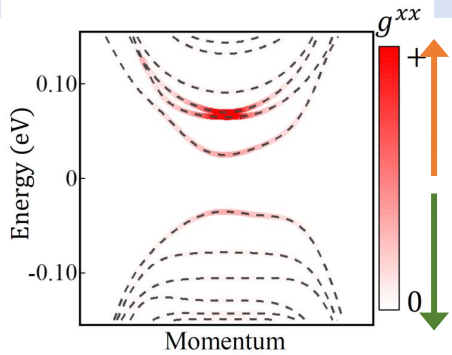
For $\mu = -50$ meV:



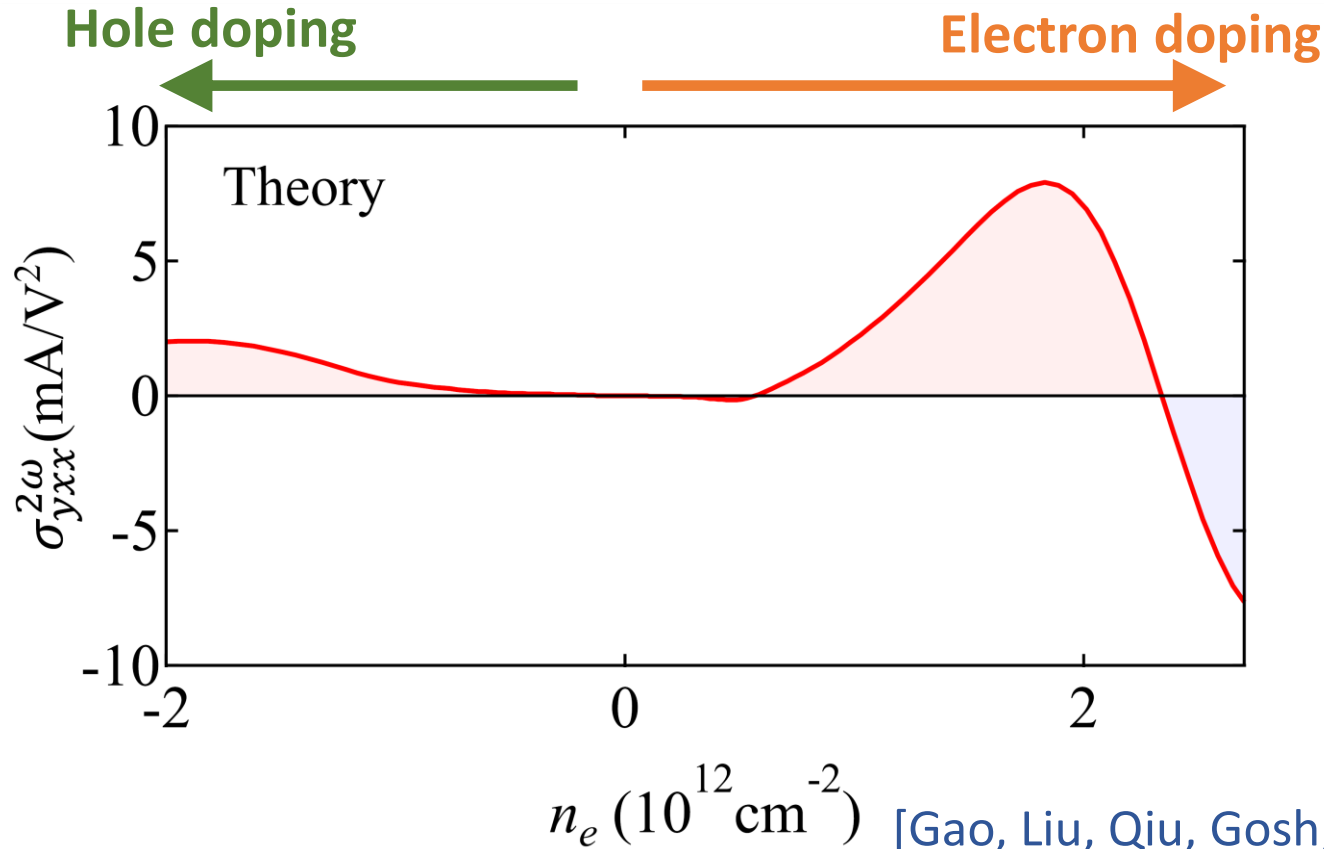
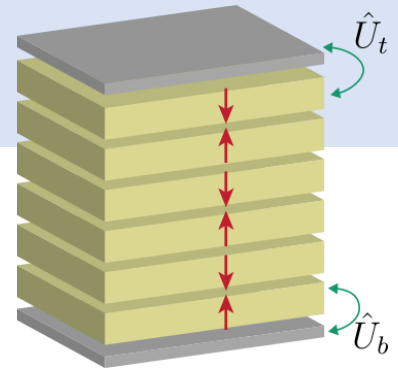
Large quantum metric
at small band gaps

$$\int_{\text{FS}} d\mathbf{k} [v_y g_{xx} - v_x g_{yx}] \neq 0$$

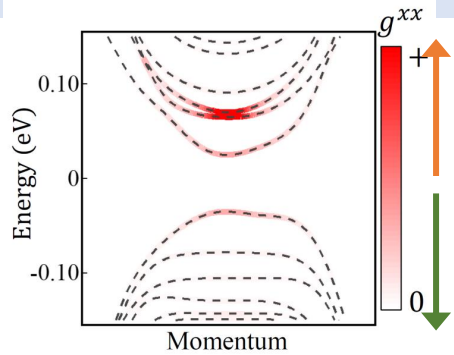
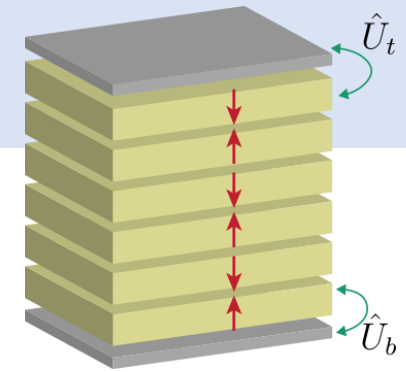
Energy dependence of the non-linear anomalous Hall effect



$$\sigma_{yxx} = 2e^3 \sum_n \int \frac{d^d k}{(2\pi)^d} \frac{v_y^n g_{xx}^{(n)}(\mathbf{k}) - v_x^n g_{yx}^{(n)}(\mathbf{k})}{\varepsilon_{n,\mathbf{k}} - \varepsilon_{\bar{n},\mathbf{k}}} \delta(\varepsilon_{n,\mathbf{k}} - \varepsilon_F) + \text{AIC}$$



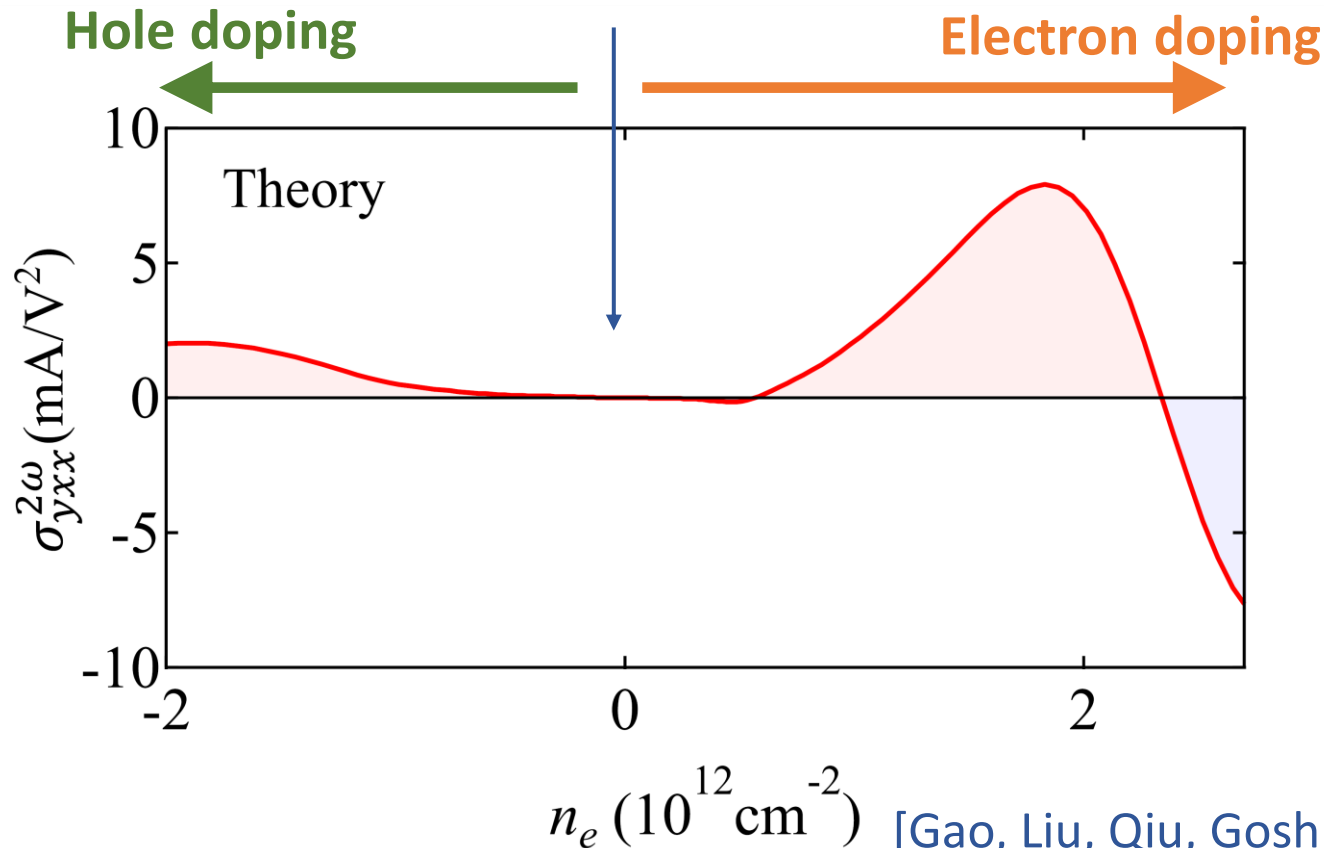
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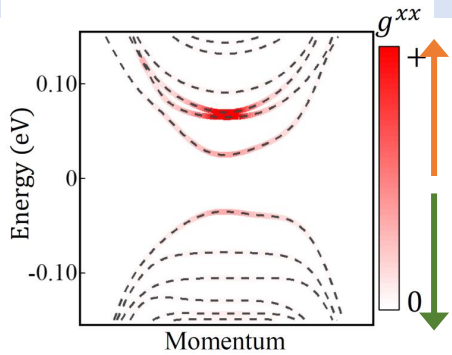
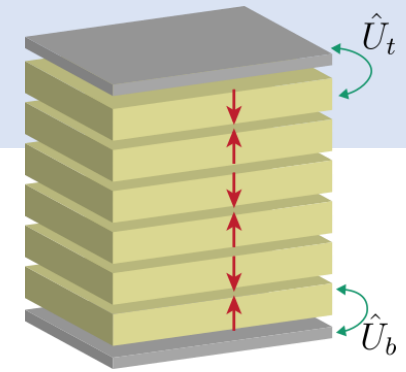
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1) Zero at charge neutrality

⇒ Fermi surface property

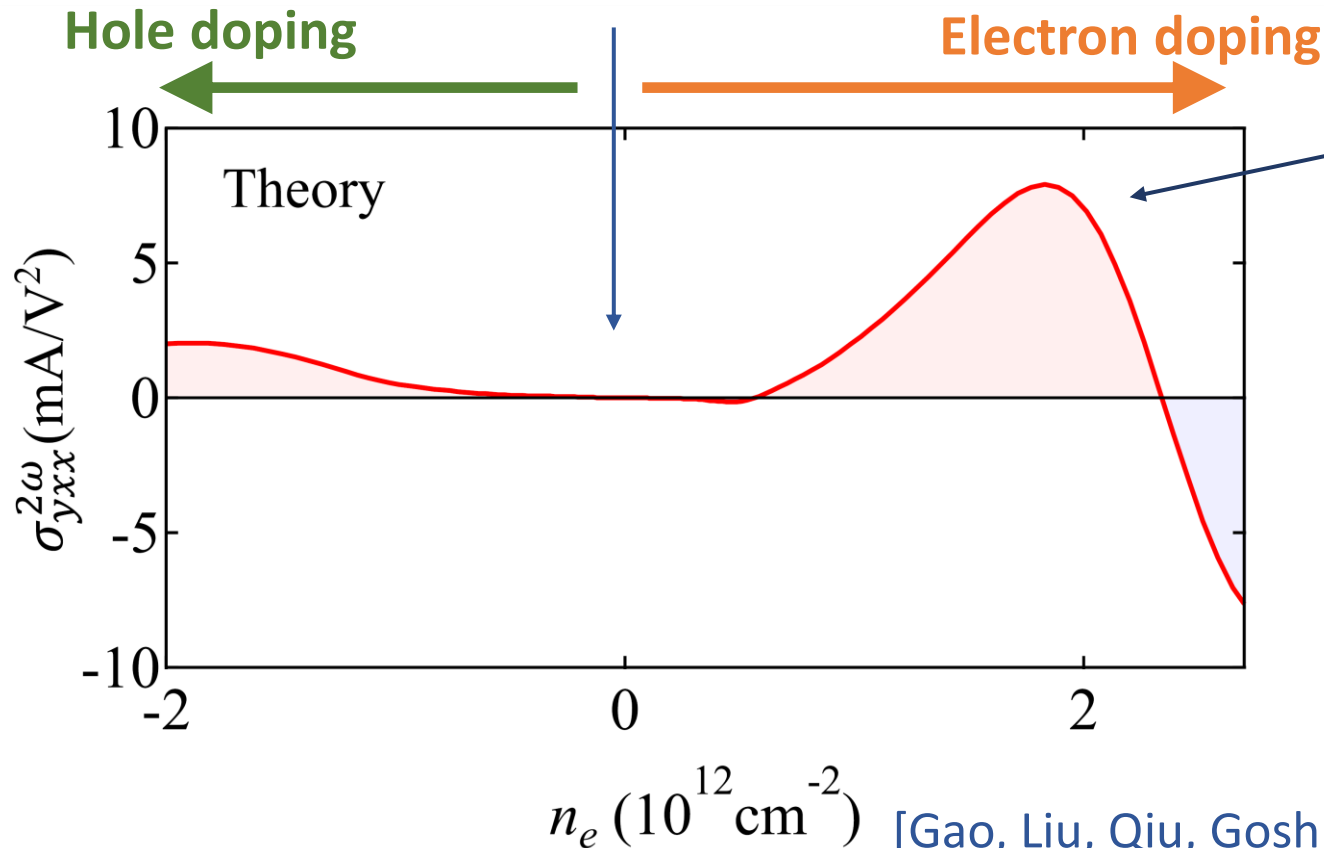


Energy dependence of the non-linear anomalous Hall effect



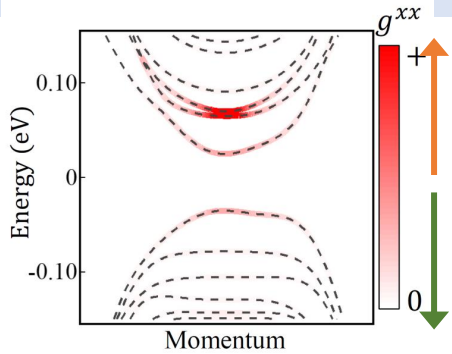
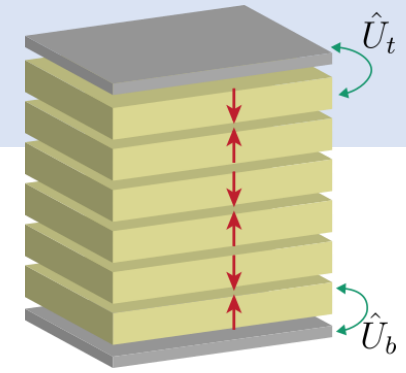
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1) Zero at charge neutrality
 $\Rightarrow$ Fermi surface property



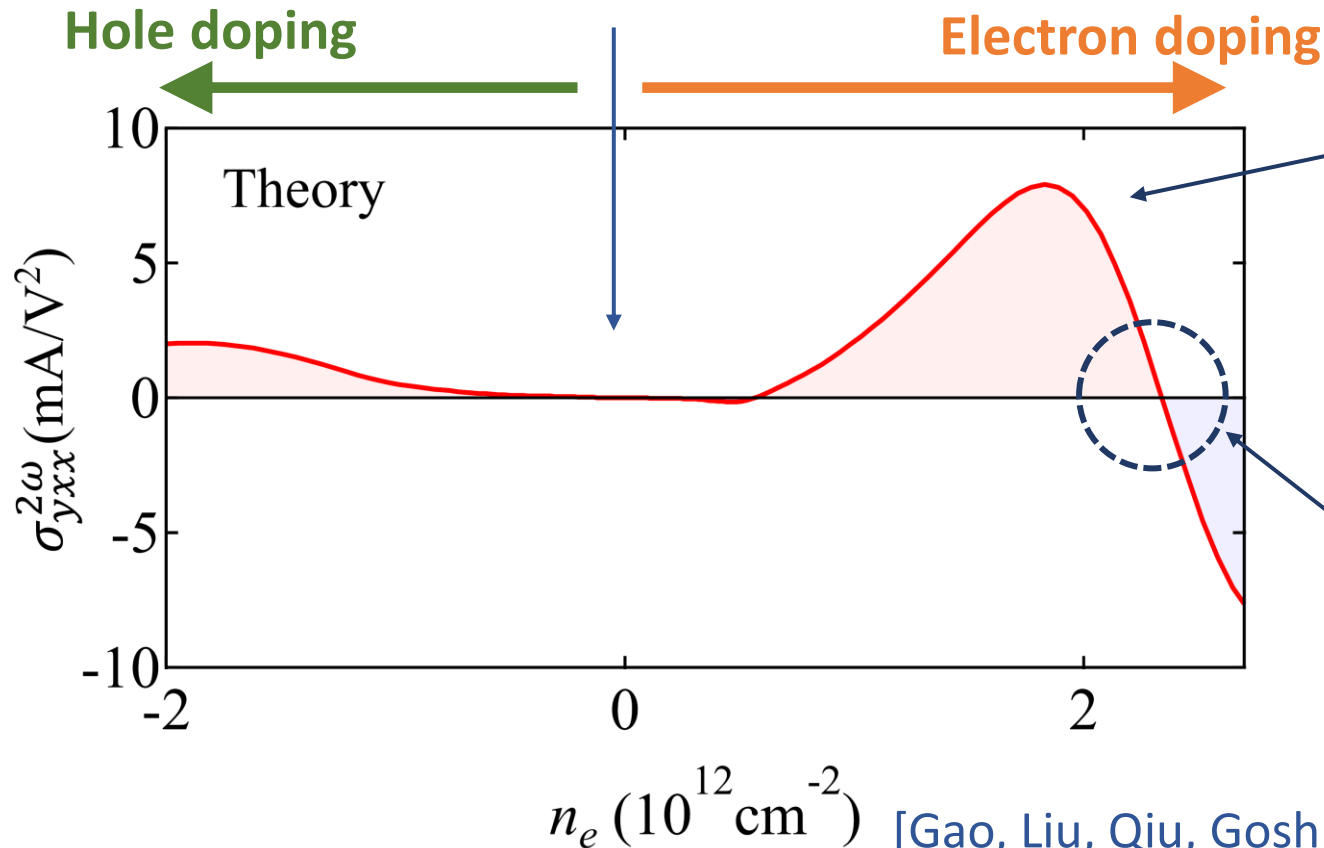
2) Larger for electron doping
 $\Rightarrow$ Larger quantum metric

Energy dependence of the non-linear anomalous Hall effect



$$\sigma_{yxx} = 2e^3 \sum_n \int \frac{d^d k}{(2\pi)^d} \frac{v_y^n g_{xx}^{(n)}(\mathbf{k}) - v_x^n g_{yx}^{(n)}(\mathbf{k})}{\varepsilon_{n,\mathbf{k}} - \varepsilon_{\bar{n},\mathbf{k}}} \delta(\varepsilon_{n,\mathbf{k}} - \varepsilon_F) + \text{AIC}$$

- 1) Zero at charge neutrality
⇒ Fermi surface property



- 2) Larger for electron doping
⇒ Larger quantum metric

- 3) Changes sign
⇒ hybridization between BP and MBT bands

$n_e (10^{12} \text{ cm}^{-2})$

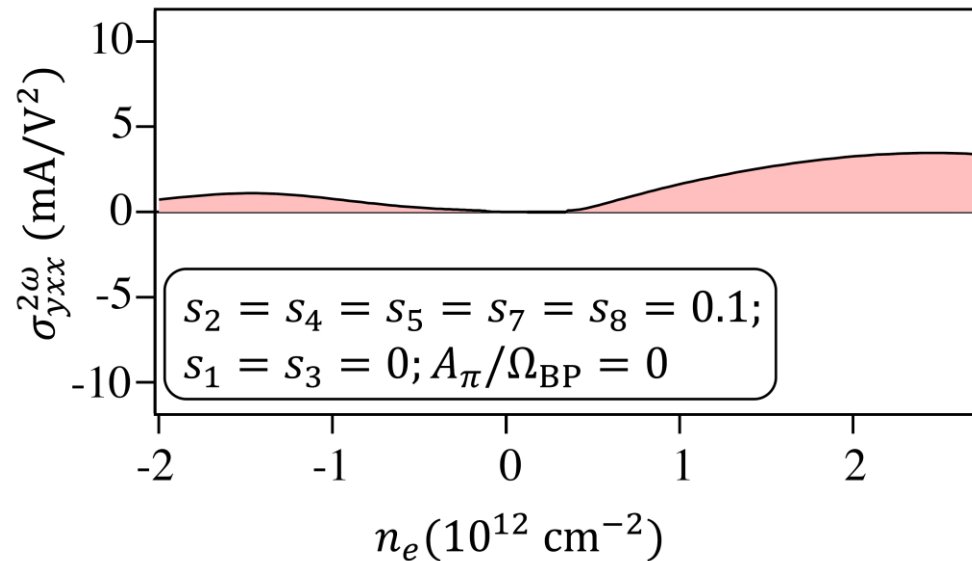
[Gao, Liu, Qiu, Gosh, [Trevisan](#) et al., Science (2023)]

Strain alone cannot capture the features of the observed Hall signal

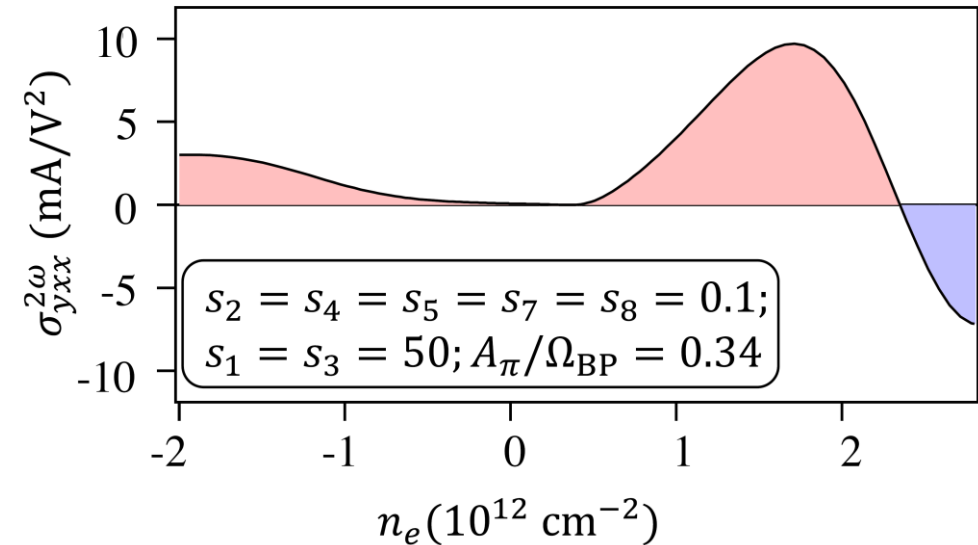
- Large mismatch between MBT and BP lattice induces strain
- New terms in the MBT minimal model

$$\hat{h}(\mathbf{k}) = \hat{h}_N(\mathbf{k}) + (-1)^\zeta \gamma_{\text{af}} \hat{h}_{\text{AFM}}(\mathbf{k}) + \gamma_s \hat{h}_s(\mathbf{k})$$

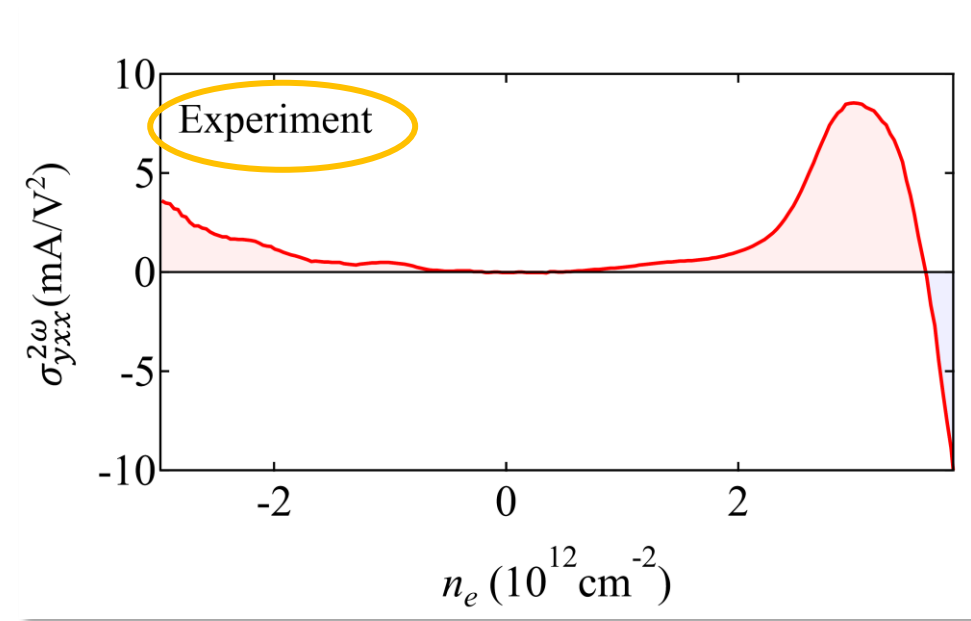
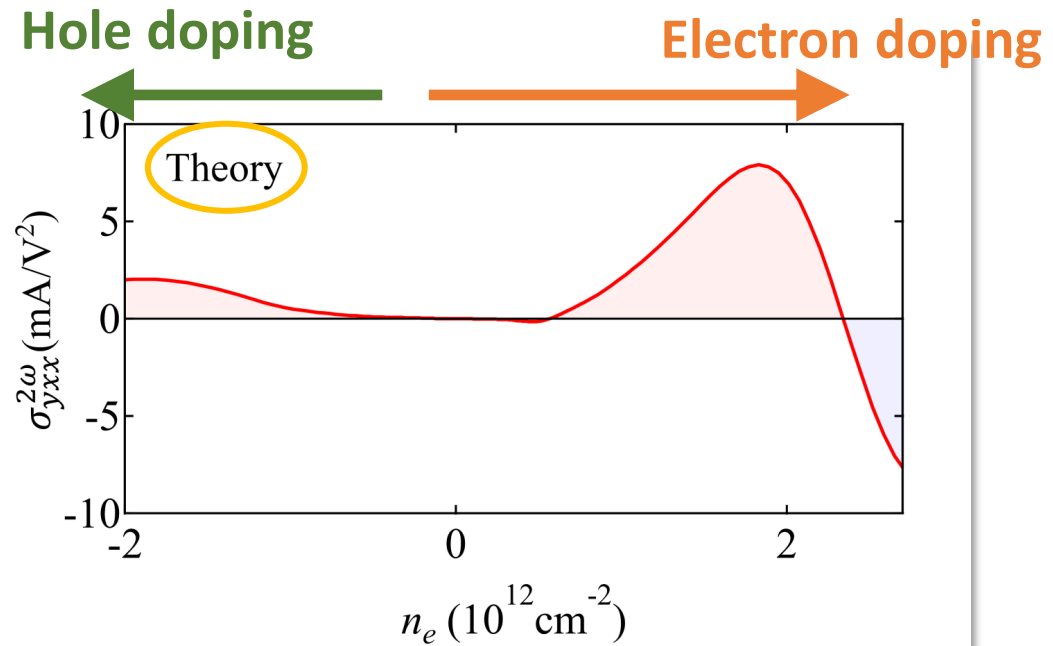
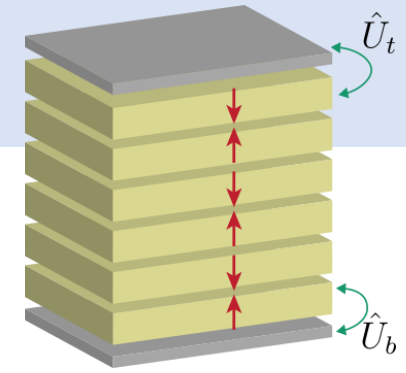
Strain only



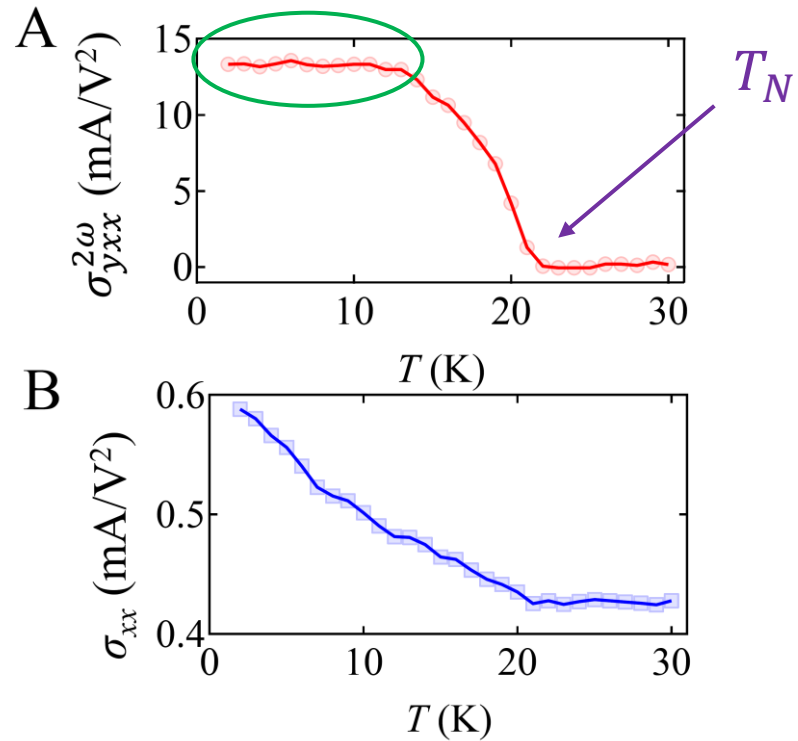
Strain and MBT-BP hybridization



Energy dependence of the non-linear anomalous Hall effect

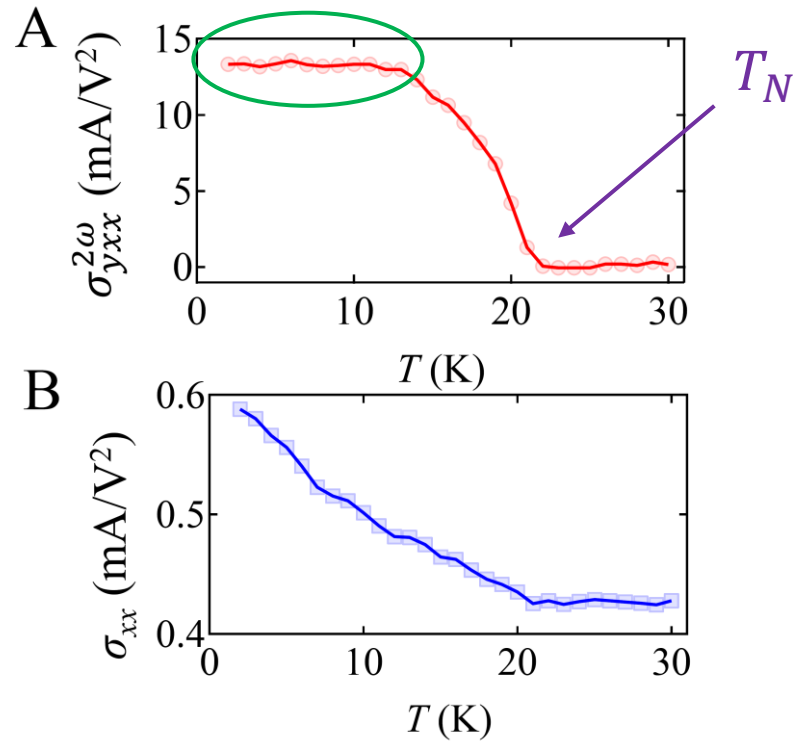


Ruling out other sources of second-order AHE



1) Finite only below $T_N \Rightarrow$ Hall signal comes from the spin texture

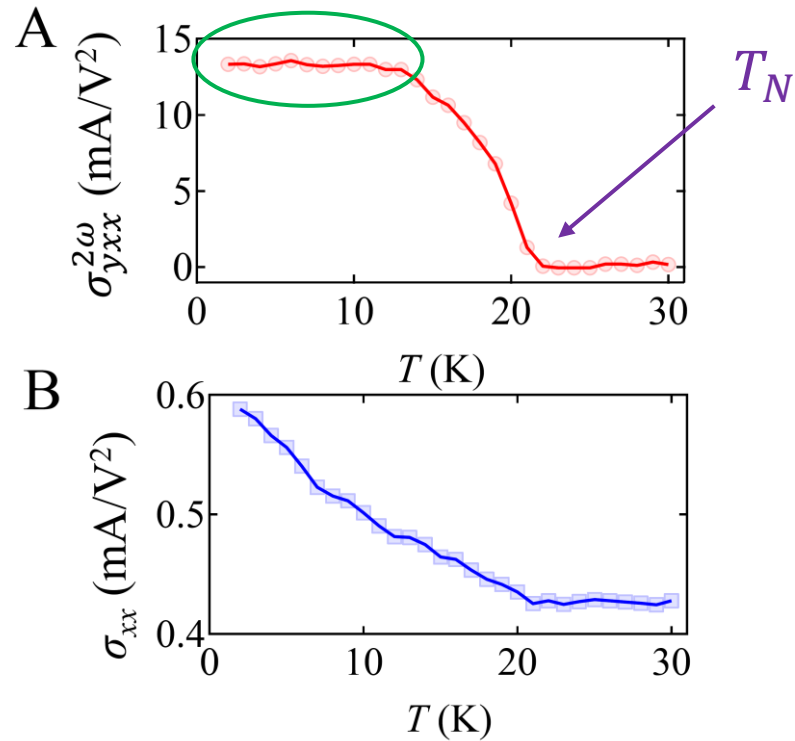
Ruling out other sources of second-order AHE



1) Finite only below $T_N \Rightarrow$ Hall signal comes from the spin texture

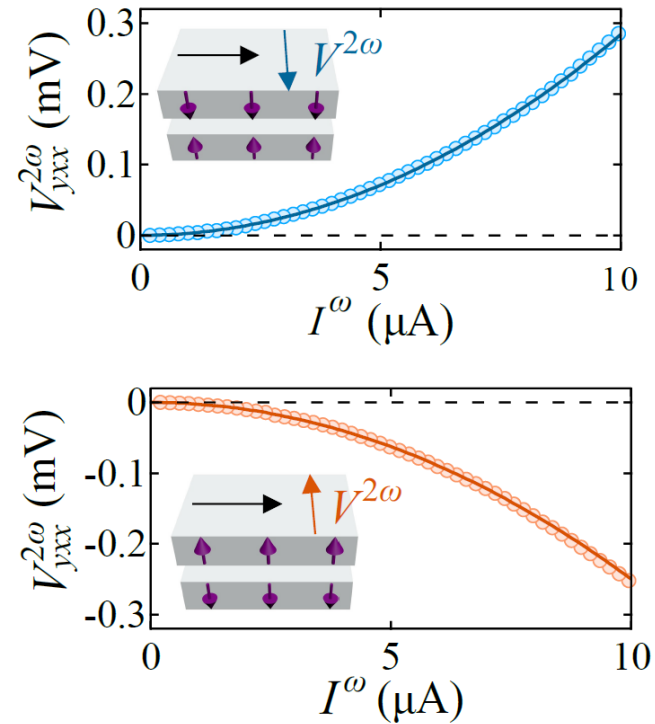
2) Independent of $\sigma_{xx} \Rightarrow$ intrinsic effect

Ruling out other sources of second-order AHE



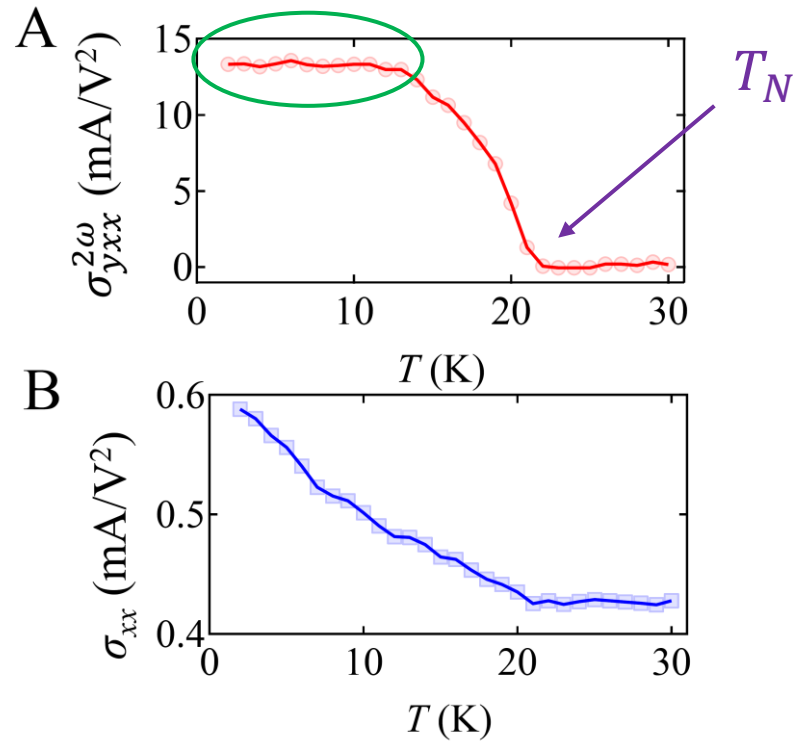
1) Finite only below $T_N \Rightarrow$ Hall signal comes from the spin texture

2) Independent of $\sigma_{xx} \Rightarrow$ intrinsic effect



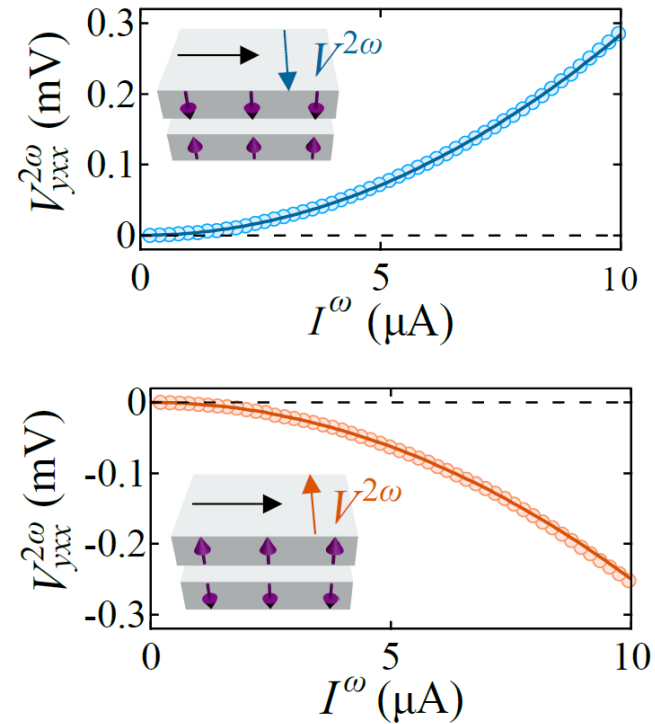
3) Hall signal changes sign under time-reversal

Ruling out other sources of second-order AHE

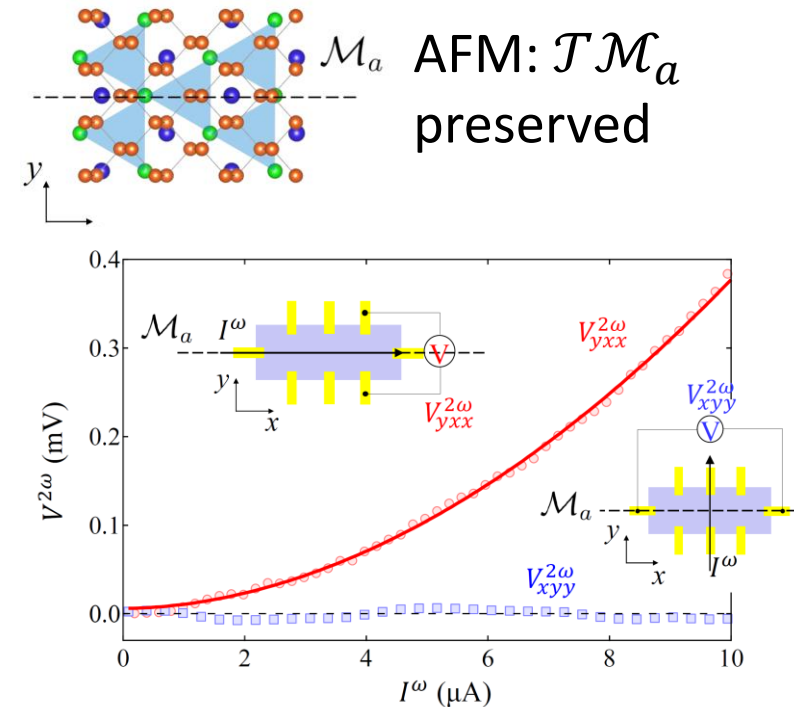


1) Finite only below $T_N \Rightarrow$ Hall signal comes from the spin texture

2) Independent of $\sigma_{xx} \Rightarrow$ intrinsic effect



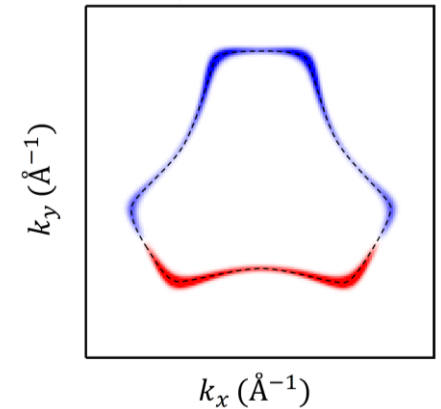
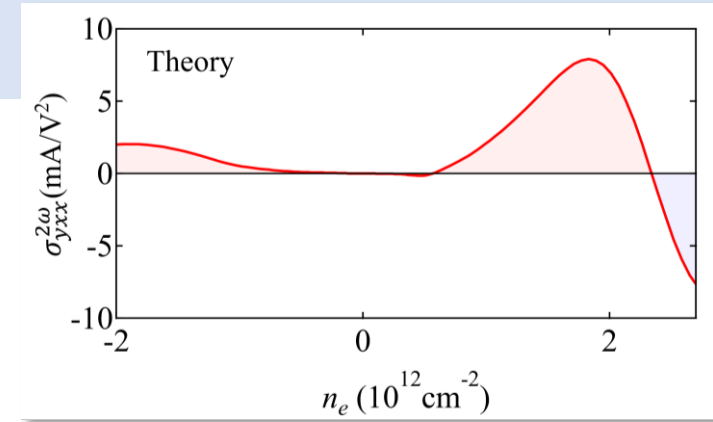
3) Hall signal changes sign under time-reversal



4) Symmetry constraint rule out Berry curvature dipole

Summary

- Second-order anomalous Hall effect
 - Extrinsic: disorder, Berry curvature multipoles
 - Intrinsic: dipoles of quantum metric
- Intrinsic component dominates in PT-symmetric materials with large quantum metric
 - BP/MBT/BP is an ideal platform
 - Main features captured by a minimal model
 - Hybridization between MBT and BP bands is essential to account for sign change of the Hall signal
- Future direction: what about multipoles of quantum metric?



[Gao, Liu, Qiu, Gosh, [Trevisan](#) et al., Science (2023)]

Thank you!

Extra Slides

Frequency dependence of the quantum metric anomalous Hall conductivity

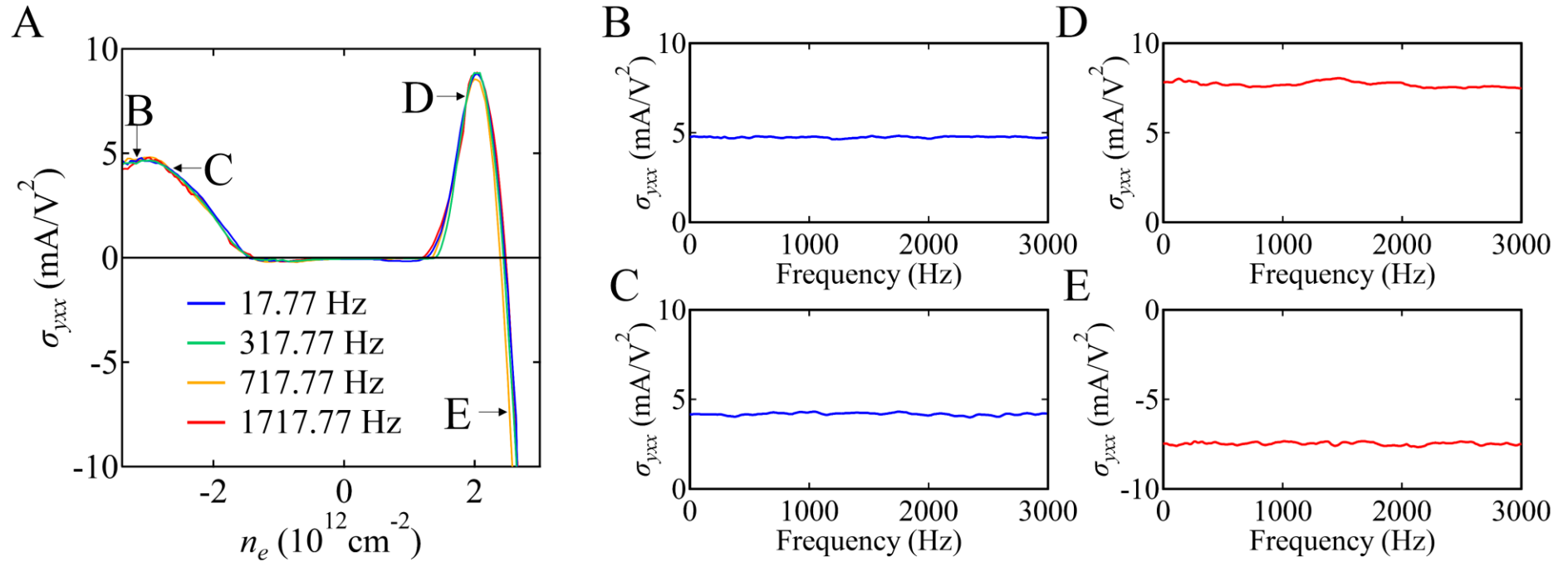


Fig. S23. Measured frequency dependence of the nonlinear Hall effect. (A) $\sigma_{yxx}^{2\omega} - n_e$ at discrete frequency ω values. (B-E) $\sigma_{yxx}^{2\omega} - \omega$ at four charge density n_e values (noted by the black arrows in panel A).

Dominant contribution of the quantum metric term

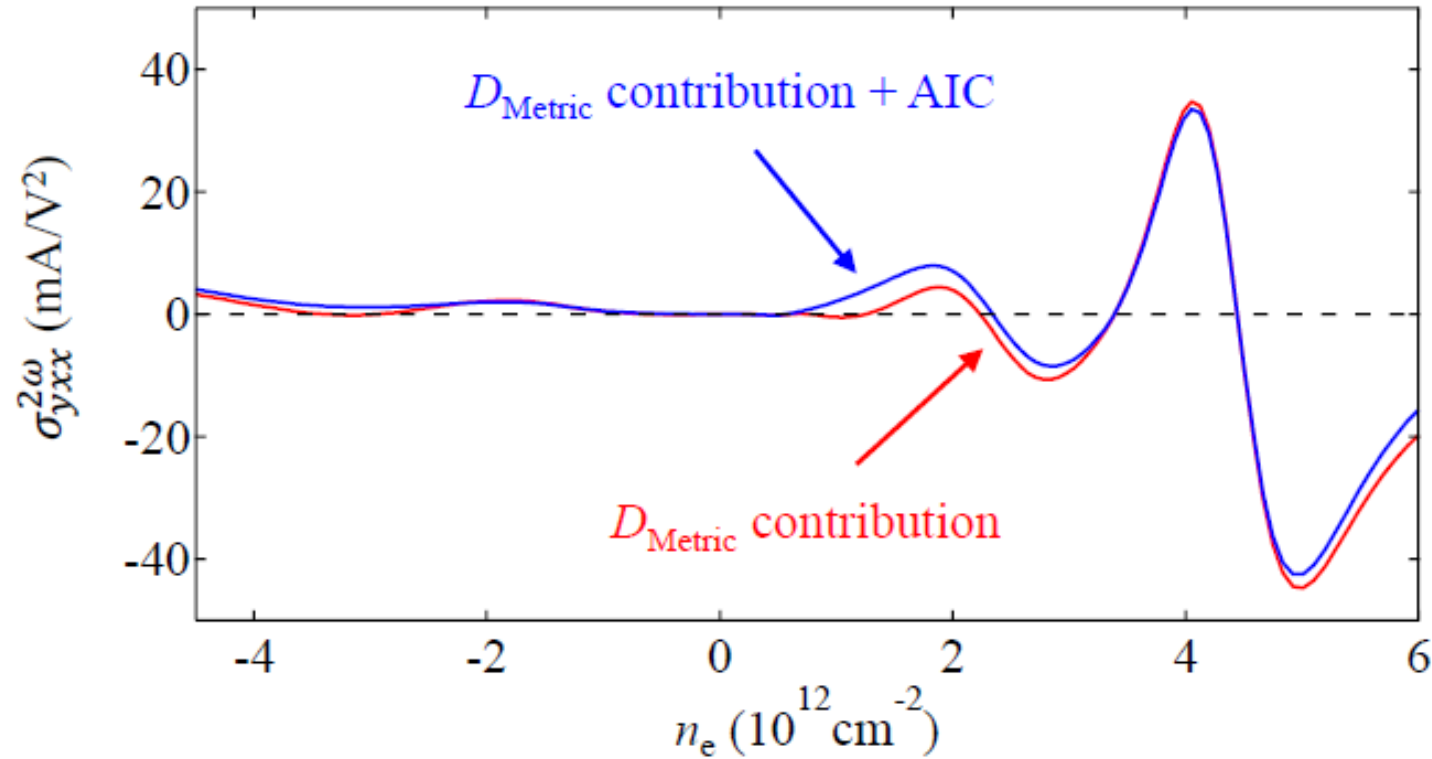


Fig. S42. Quantum metric dipole dominated nonlinear Hall conductivity. Two-band model (quantum metric dipole D_{Metric} contribution) and multiband model (D_{Metric} + additional inter band contributions AIC) calculated nonlinear Hall conductivity as a function of carrier density. The nonlinear Hall signals are dominated by the quantum metric dipole contribution.